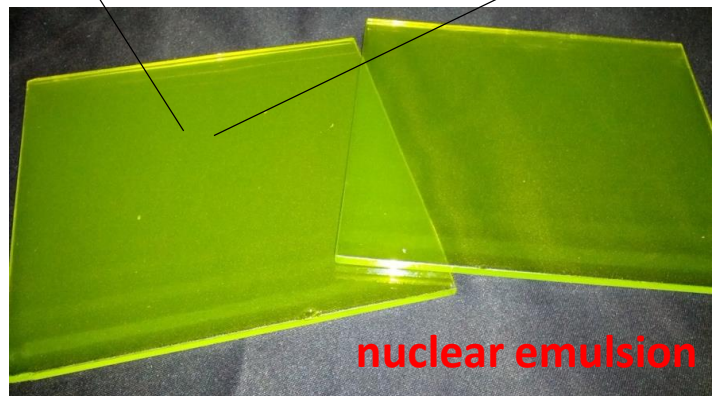
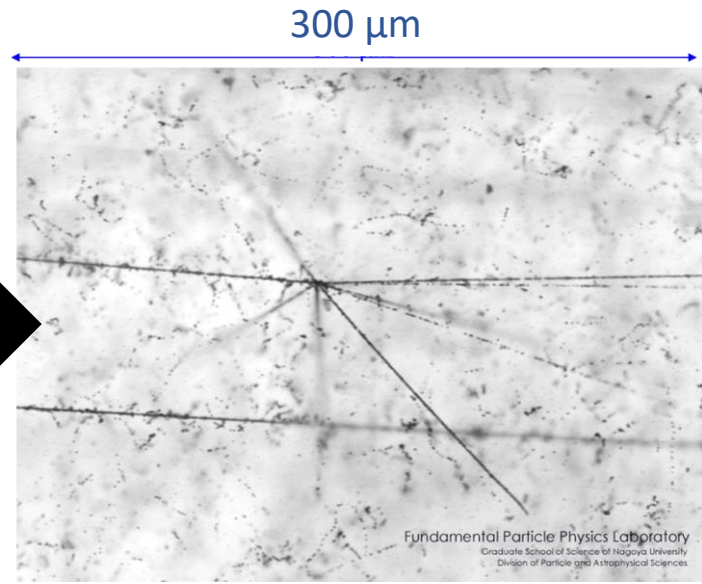
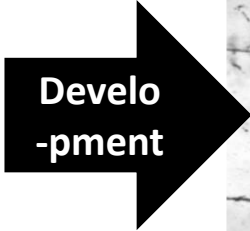
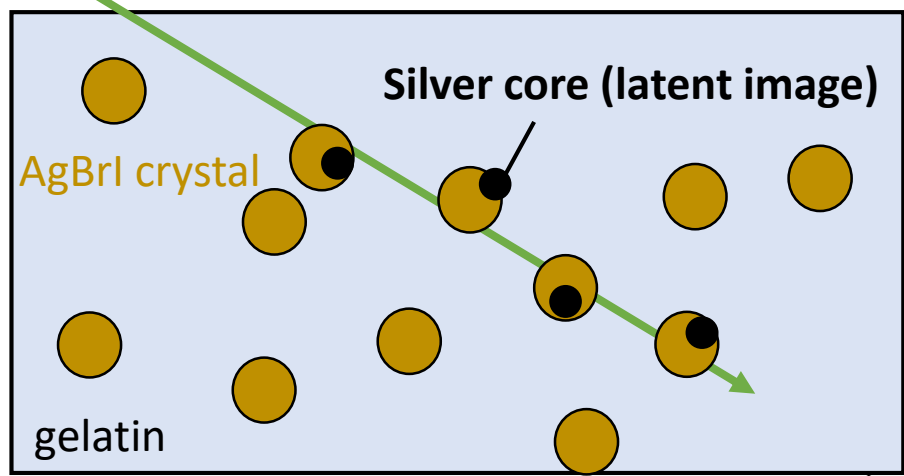


Study for photon emission response to charged particles of NIT

Hiromasa Ichiki

Nuclear Emulsion

charged particle



density : 3.2-3.4 g/cm³

40nm crystal

200nm crystal

SEM image

500nm

submicron spacial resolution

“photosensitive mechanism” by light or charged particles

The sensitization mechanism is the same ?

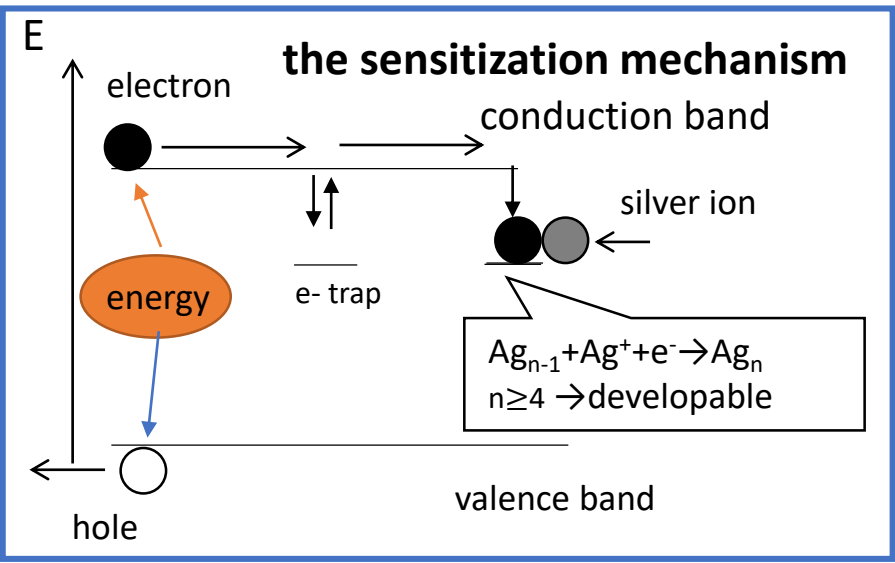
	dE/dx in AgBrI	*e-h pairs generated in the 40 nm crystal	*e-h pairs generated in the 200 nm crystal
α ray	300 [keV/μm]	~2000 [/fs]	~10000 [/fs]
**laser		~0.001 [/fs]	~0.01 [/fs]

**1 kW、φ 1mm

*1 e-h pair/ 5.8 eV (K. A. Yamakawa, Phys. Rev. 82, 4 (1951))

Charged particle penetrate the crystal

→ a huge number of e-h pair in a very short time



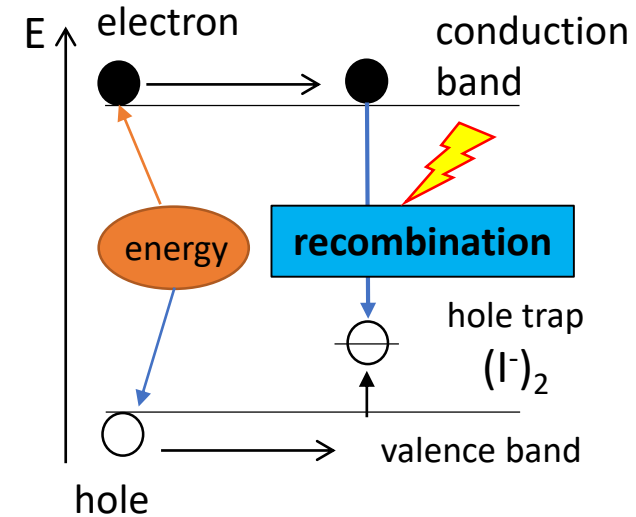
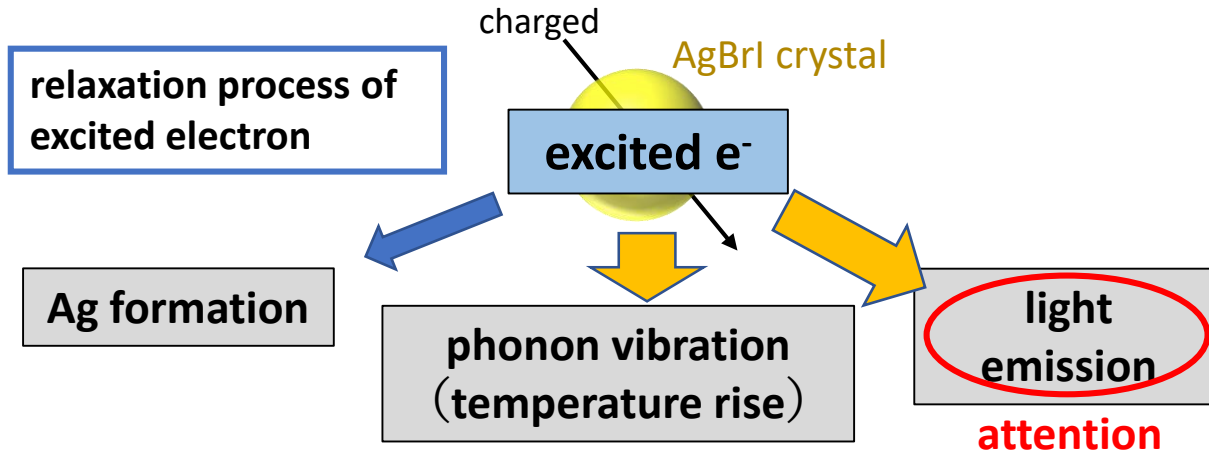
presence of enormous e-h pairs



recombination may be intense
→ Ag formation is inefficient.

Is the e-h pair used in other processes ?

Focus on the light emission process



Research on the light emission of silver halide has been reported.

- light excitation (mainly)
- various crystal shapes (ex. square, octahedron) and dopes

AgBrI crystal (used in our study)

- wavelength ~550 nm (luminescence center is iodine)

◎ **The light emission response to charged particle has not been studied.**

a lot of information independent of silver particles (tracks) observation.

→ understand the phenomenology when charged particle pass through the crystal

Motivation

- Understanding of physical properties of crystals
 - wavelength, amount of luminescence, relaxation time
 - ⇔ depth of the electron trap (⇔ Ag particle formation)
 - change the added chemical
 - change the crystal size
 - ⇒ **Luminescence become a new evaluation indicator.**
-
- Application to elementary particle experiment
 - Trigger event location by light emission.
 - no need to analyze the all emulsion.
 - particle ID (difference in the number of e-h pairs generated in a crystal)
 - wavelength/amount of luminescence/relaxation time
 - identify α ray、 β ray、 nuclear recoil

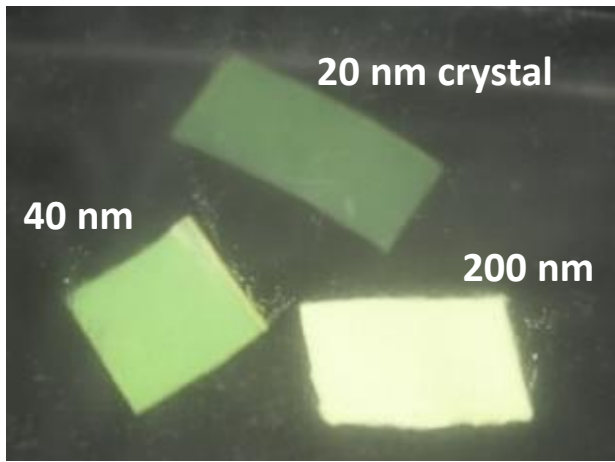
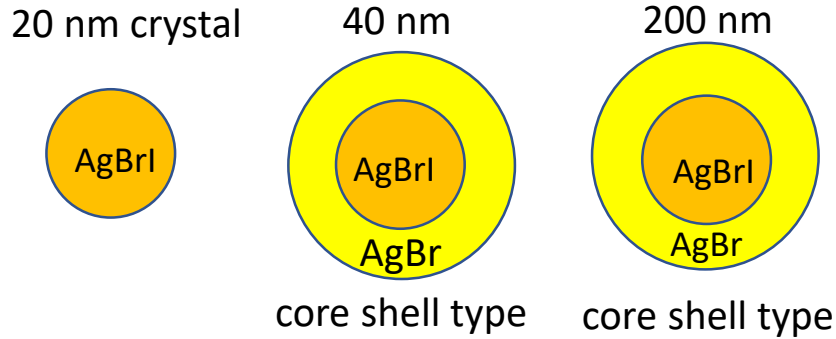
contents

- Observation of luminescence with human eyes
 - light excitation
 - charged particle excitation

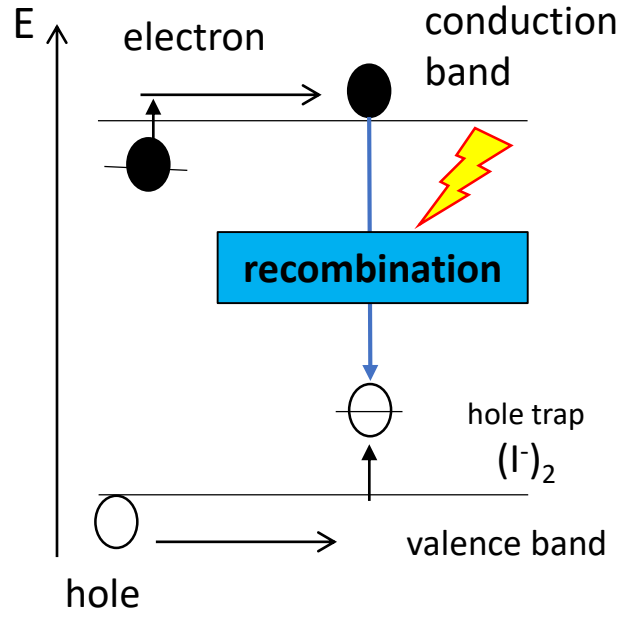
- Quantitative evaluation with cryostat
 - MPPC (Multi Pixel Photo Counter)
 - irradiation of α ray
 - irradiation of γ ray

demonstration of luminescence by light excitation

- to reduce thermal deactivation, observed at liquid nitrogen (Lq. N₂) temperature

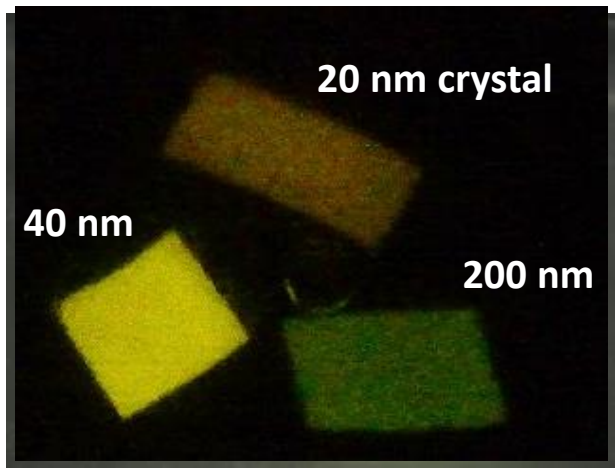
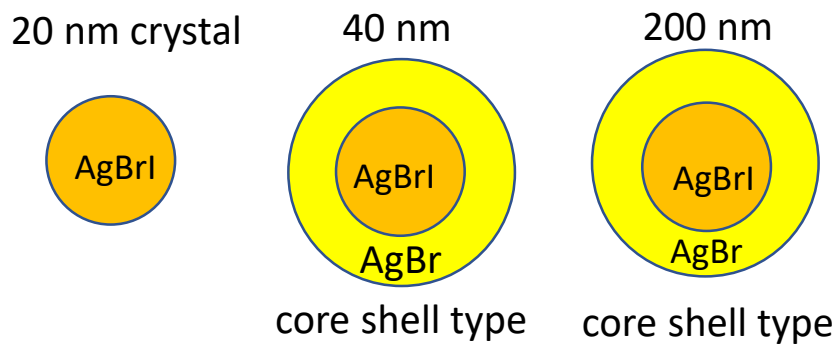


expose fluorescent lamp

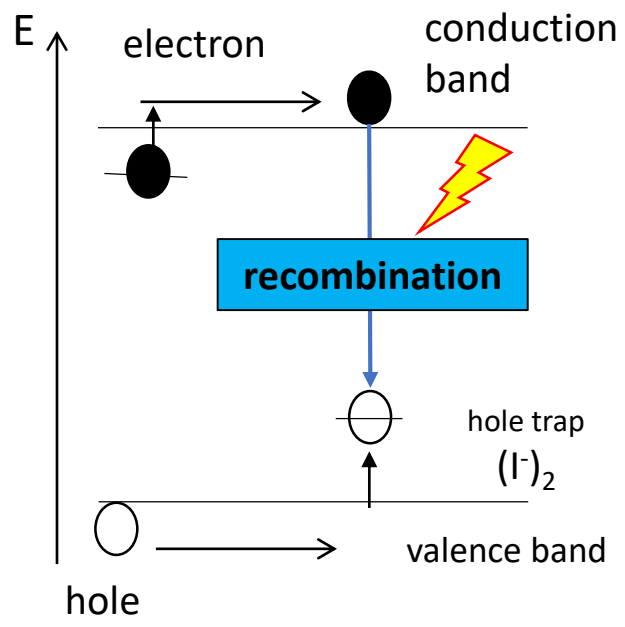


demonstration of luminescence by light excitation

- to reduce thermal deactivation, observed at liquid nitrogen (Lq. N₂) temperature



200 nm : ~1 s
20 nm : ~ 4 s
40 nm : ~ 7 s

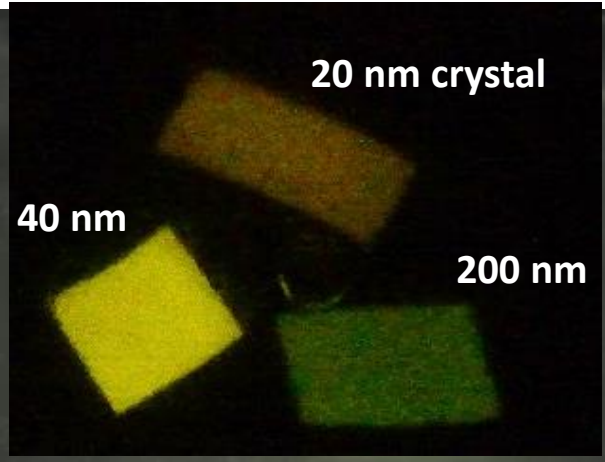
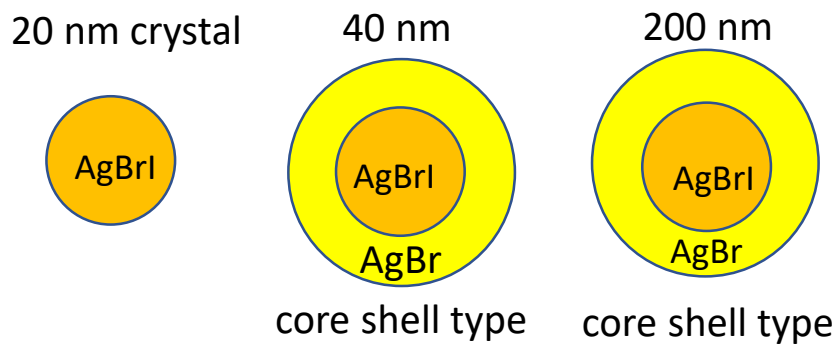


Confirmed the phosphorescence of emulsion by light excitation

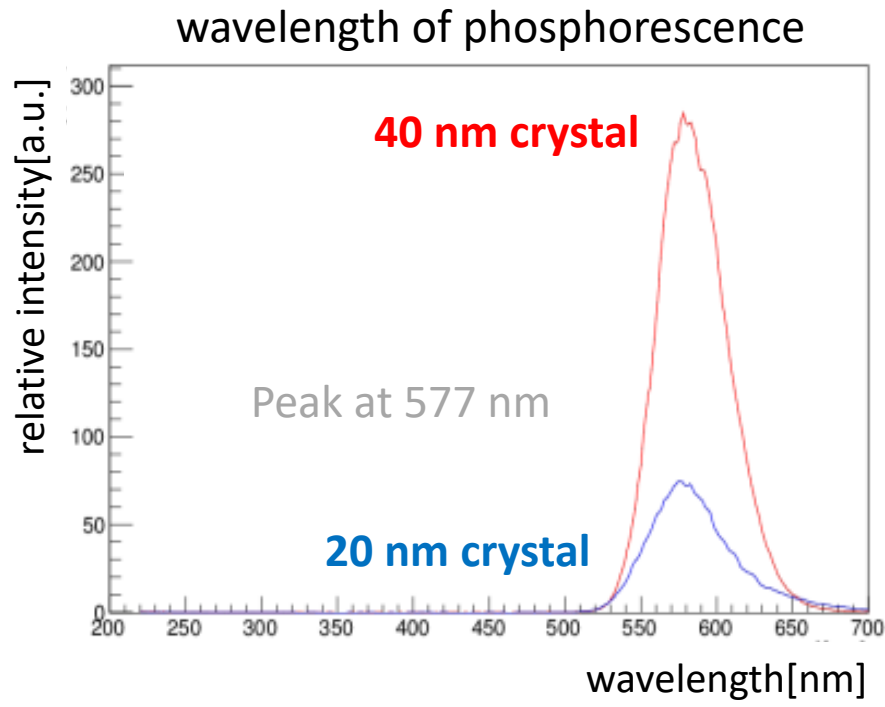
evaluate NIT (40 nm crystal emulsion) that showed strongest luminescence

demonstration of luminescence by light excitation

- to reduce thermal deactivation, observed at liquid nitrogen (Lq. N₂) temperature



200 nm : ~1 s
20 nm : ~ 4 s
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Confirmed the phosphorescence of emulsion by light excitation

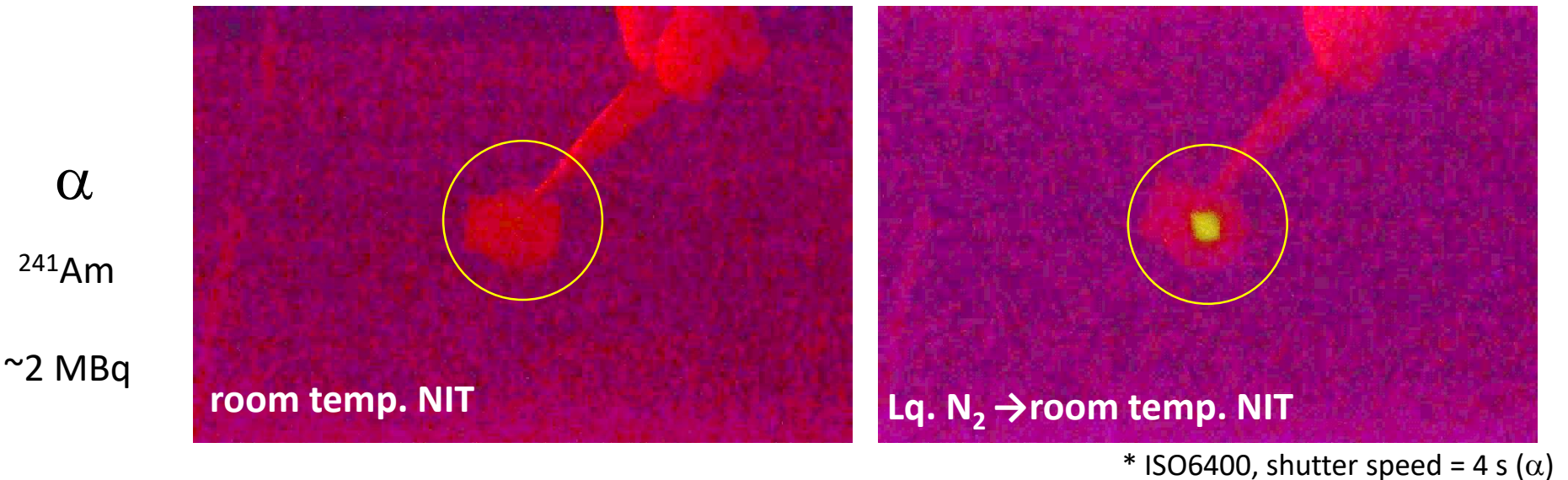
evaluate NIT (40 nm crystal emulsion) that showed strongest luminescence

demonstration of luminescence by charged particle excitation

Irradiated α -ray to NIT under stable lq. N₂ temp.

→ Light emission could not be confirmed by human eyes

⇒ observed thermally stimulated (temp. rising) NIT



**Confirmed the luminescence of emulsion
by charged particle excitation !**

→ then, quantitative evaluation

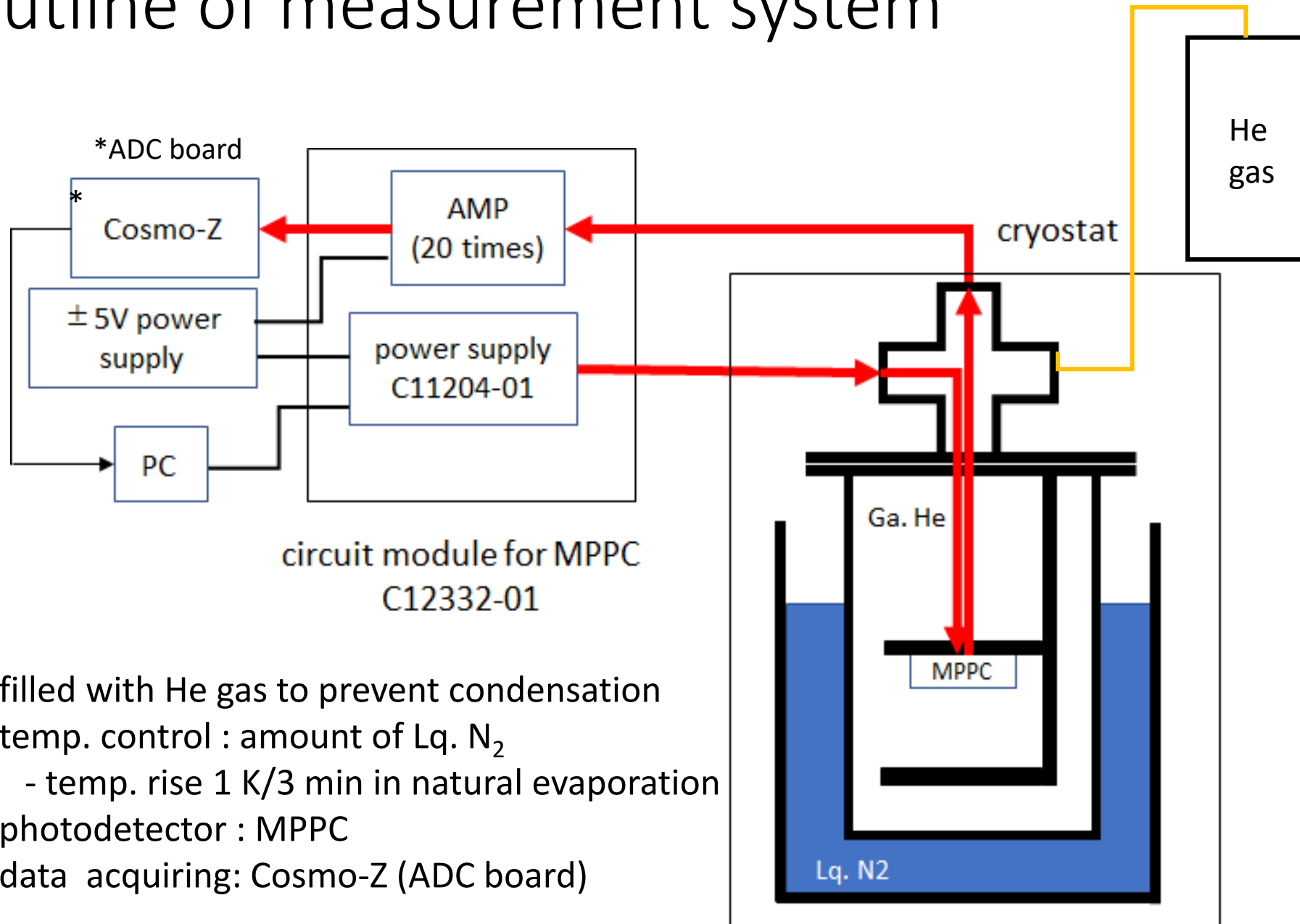


contents

- Observation of luminescence with human eyes
 - light excitation
 - charged particle excitation

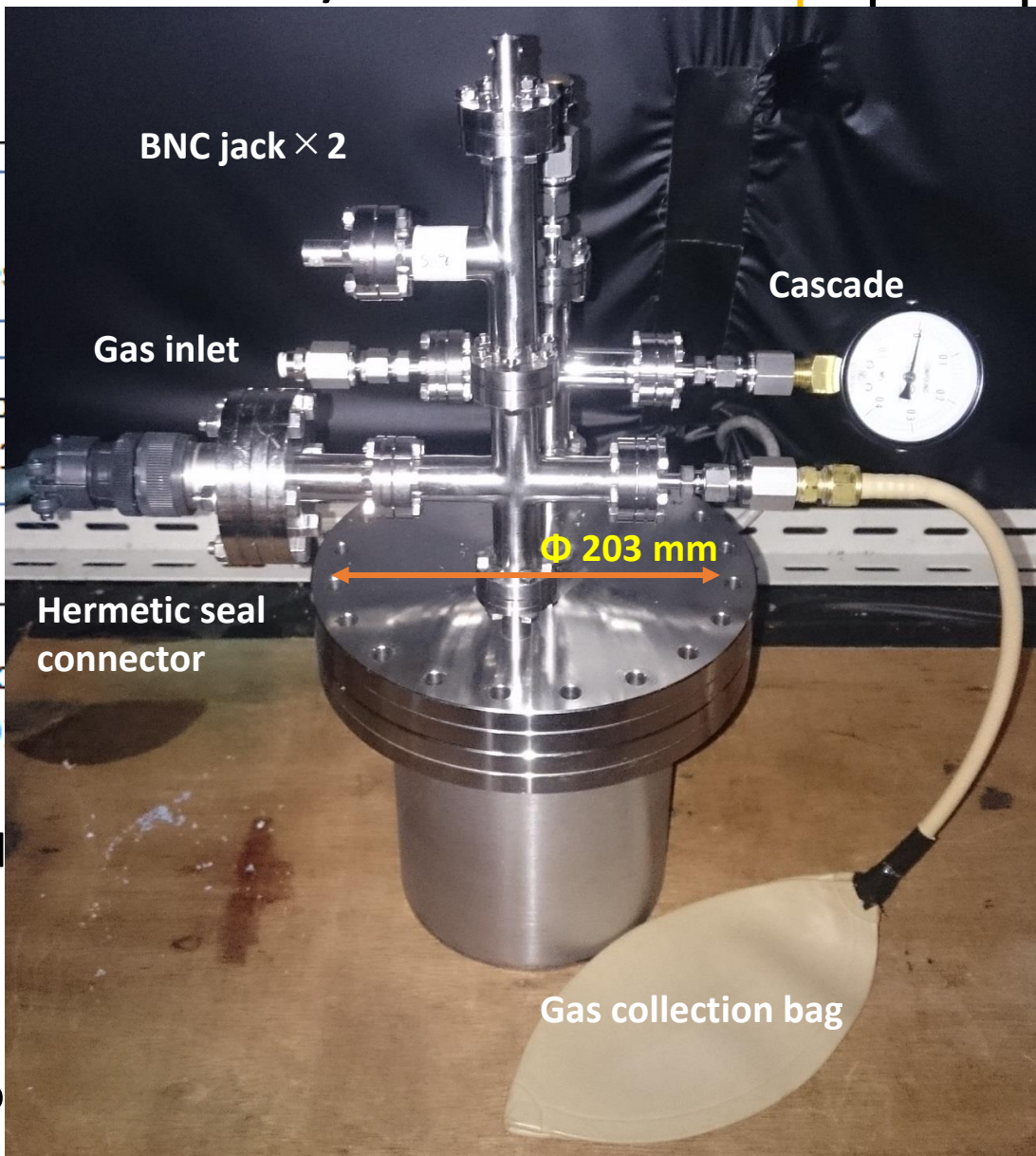
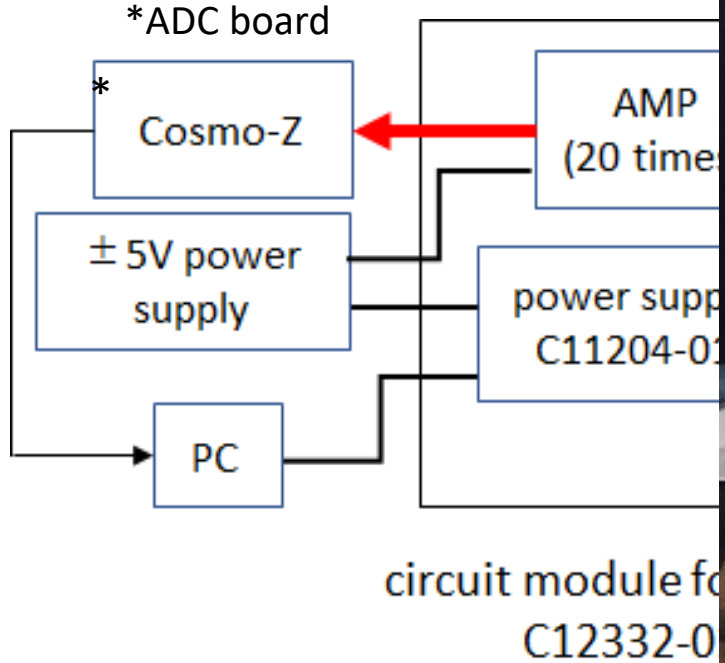
- Quantitative evaluation with cryostat
 - MPPC (Multi Pixel Photo Counter)
 - irradiation of α ray
 - irradiation of γ ray

Outline of measurement system



- filled with He gas to prevent condensation
- temp. control : amount of Lq. N₂
 - temp. rise 1 K/3 min in natural evaporation
- photodetector : MPPC
- data acquiring: Cosmo-Z (ADC board)

Outline of measurement system



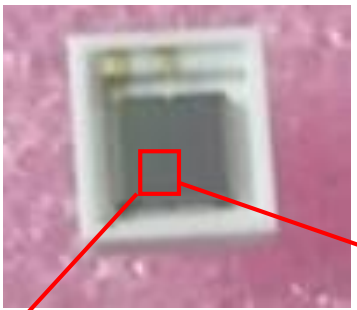
- filled with He gas to prevent condensation
- temp. control : amount of Lq. N₂
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- photodetector : MPPC
- data acquiring: Cosmo-Z (ADC board)

MPPC

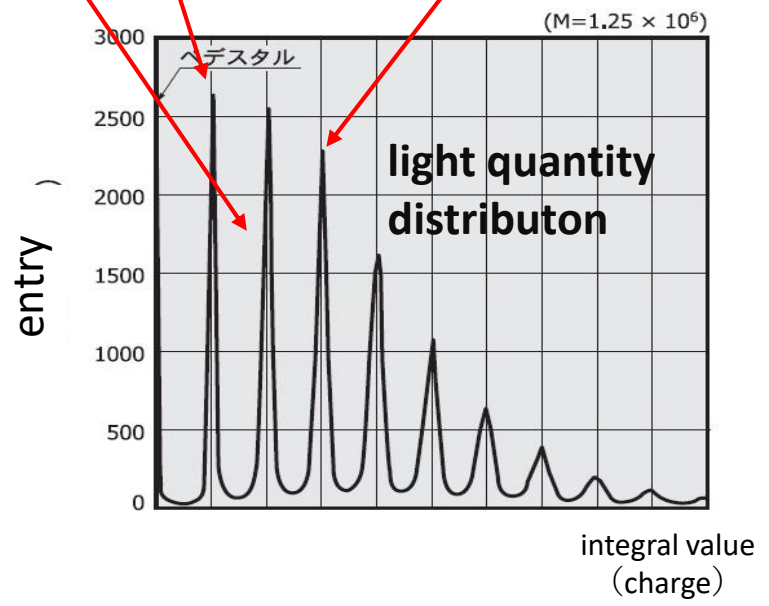
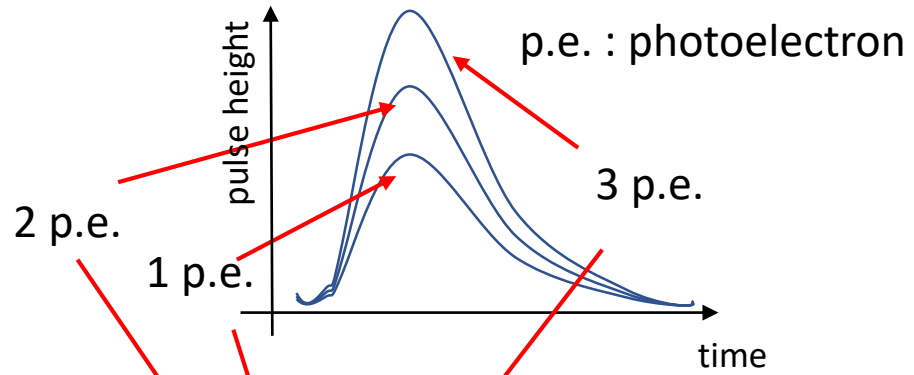
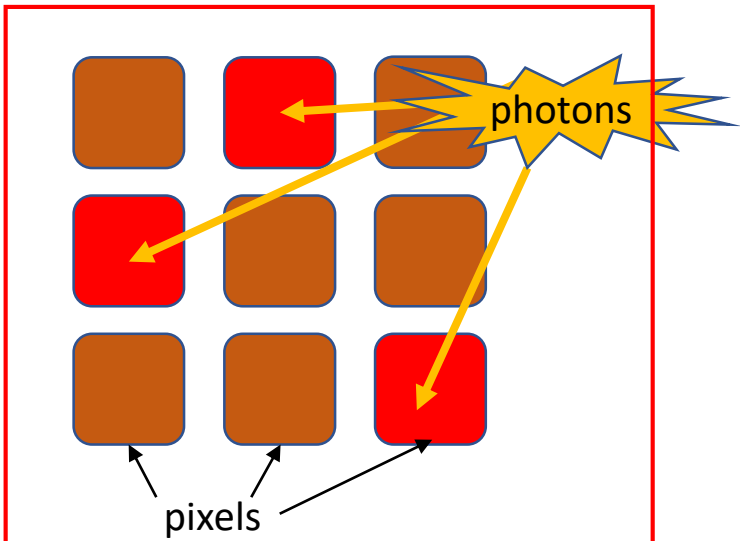
MPPC (Multi Pixel Photo Counter)

- a function to multiply the generated carriers by avalanche multiplication
- output signal is proportional to the # of pixels which detect a photon at the same time

S13370-3050CN
(VUV-MPPC)



effective area : 3 mm*3 mm
number of pixels : 3600
aperture ratio: 60 %



(from Hamamatu Photonics handbook)

MPPC calibration

operate MPPC with applied voltage (V_{bias})

$$V_{bias} = V_{bd} + V_{over}$$

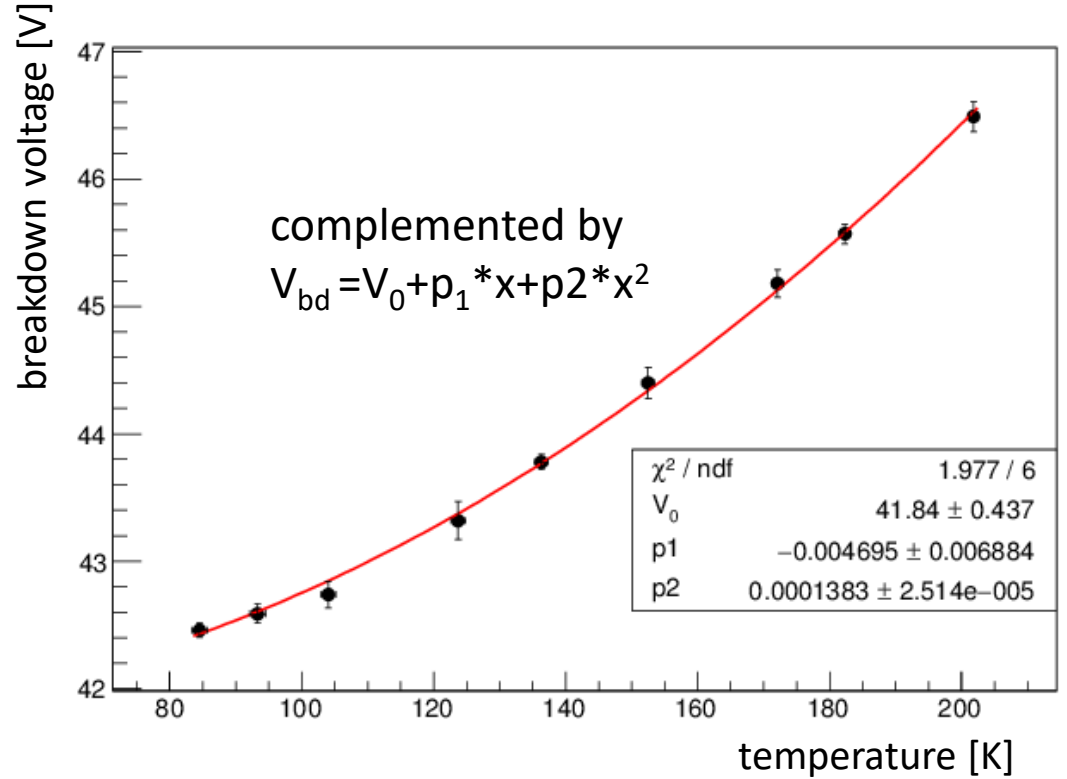
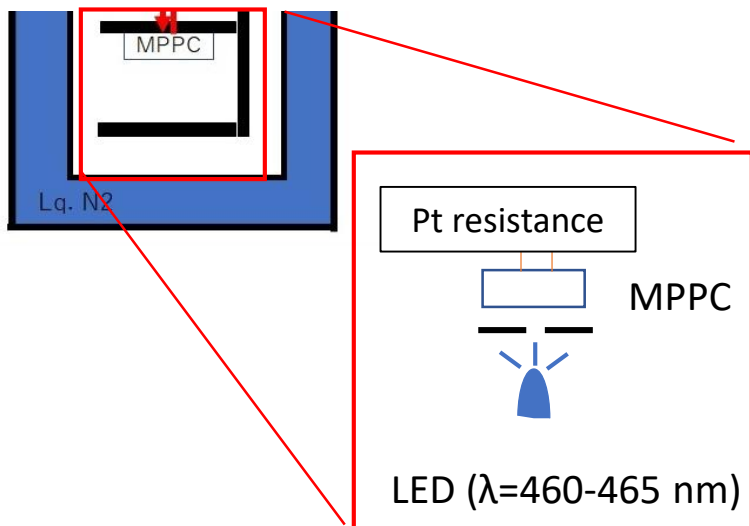
V_{bd} : voltage at which avalanche multiplication starts
(break down voltage)

V_{over} : over voltage

V_{bd} has temp. dependence \rightarrow calibration is required.

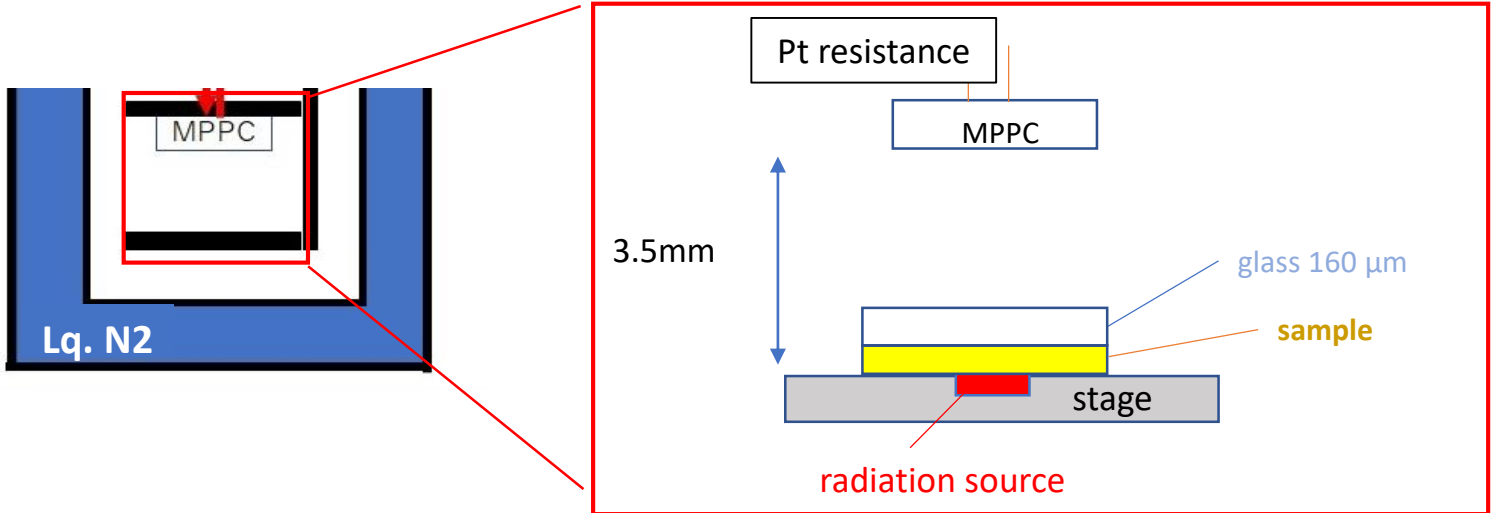
(gain and the ratio of peculiar noise of MPPC change)

We obtained V_{bd} temp. dependence using LED.



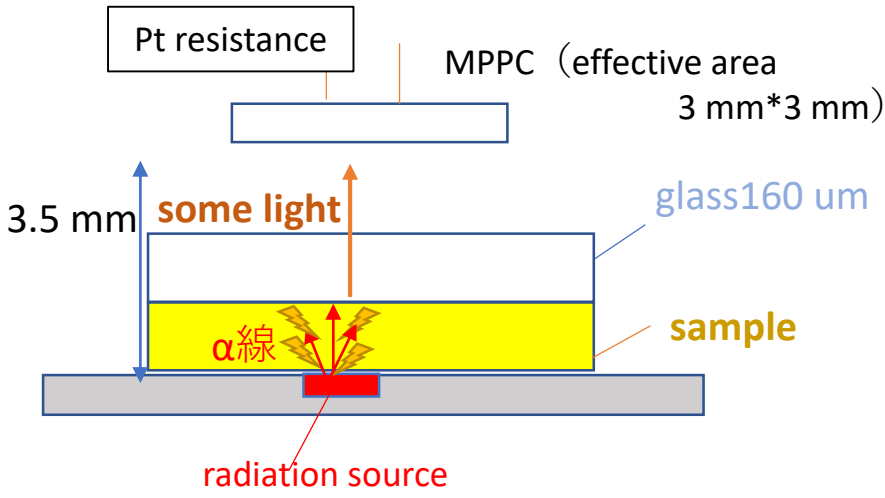
irradiation of α ray

irradiation of α ray



○ Radiation source
 ^{241}Am (α) 5.48 MeV
 33.0 [1/s]
 1 mm*1 mm

used samples
 NIT 38 μm *7 mm*3 mm (pellicle : w/o base)
 gelatin 40 μm *7 mm*3 mm

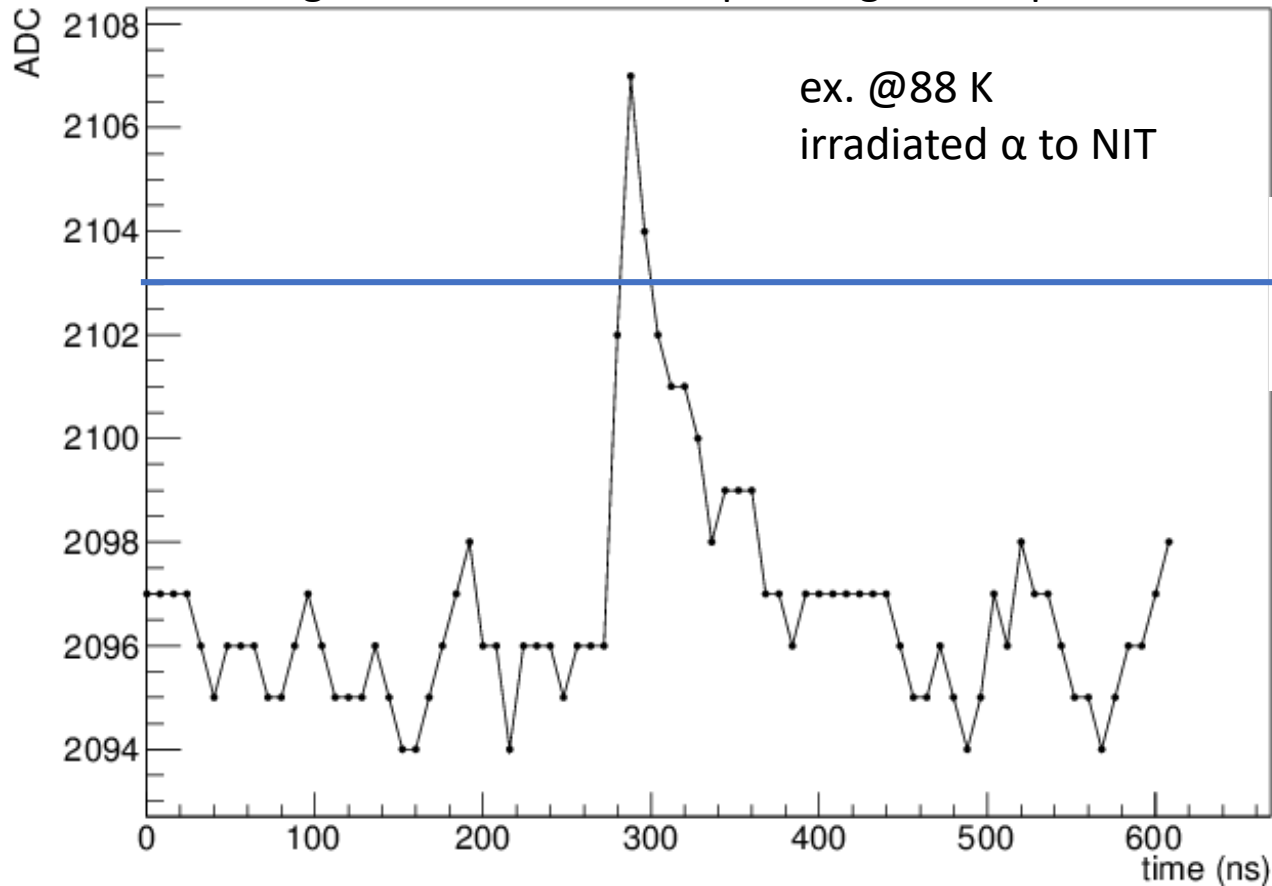


compared the results between samples

Geometric detection efficiency $\sim 5.8\%$

data acquiring · processing

Signal waveform corresponding to one photon



Threshold : ADC 2103
(detect 1 photon signal
99.3%)

- data acquiring : 88 K, 93 K - 203 K (every 10 K) for 60 s
- applied voltage (V_{bias}) was set to

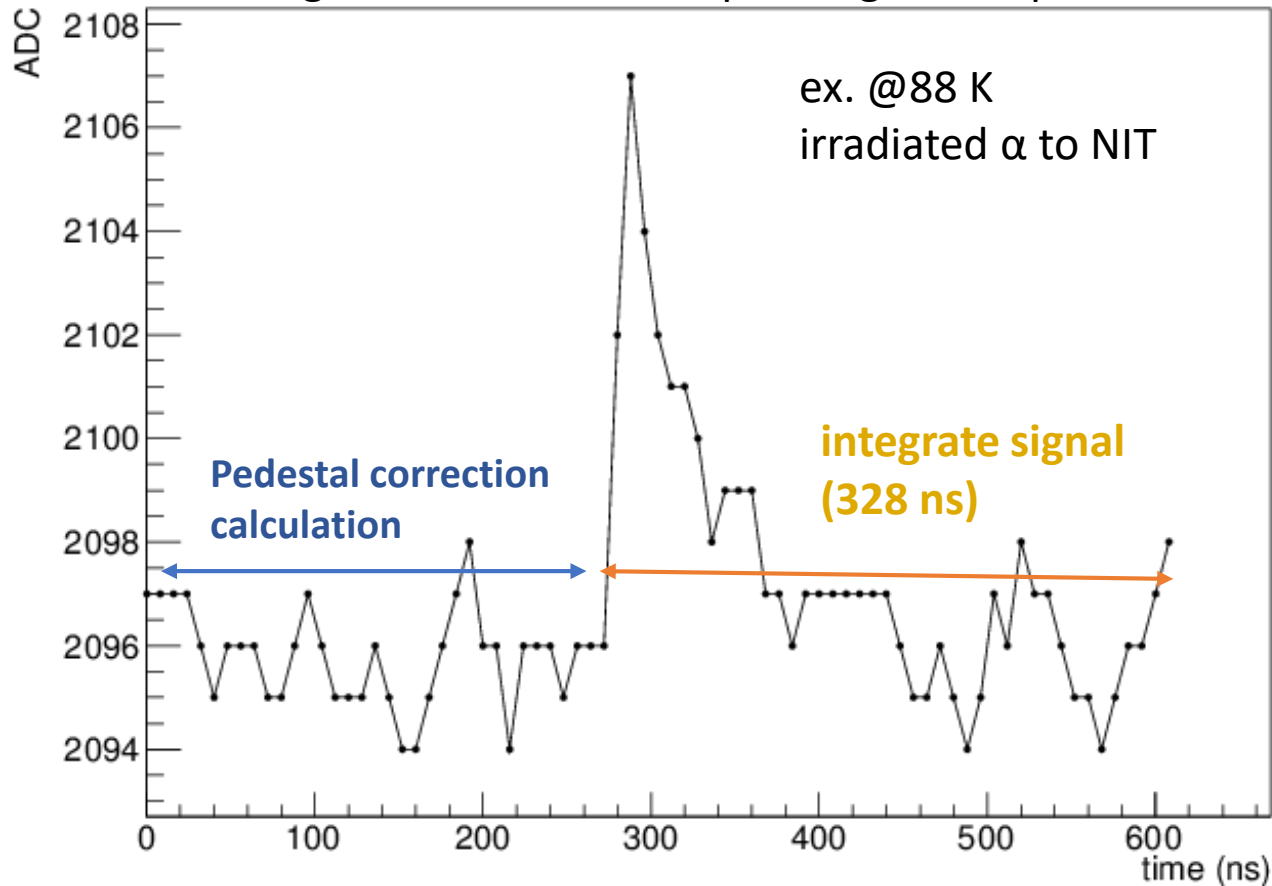
✂ 104 K, 183 K, 193 K, 203 K

the applied voltage was 0.1 V higher than the calibrated value.

→ Several % of peculiar noises of MPPC might increase.

data acquiring · processing

Signal waveform corresponding to one photon



- data acquiring : 88 K, 93 K - 203 K (every 10 K) for 60 s
- applied voltage (V_{bias}) was set to

✘ 104 K, 183 K, 193 K, 203 K

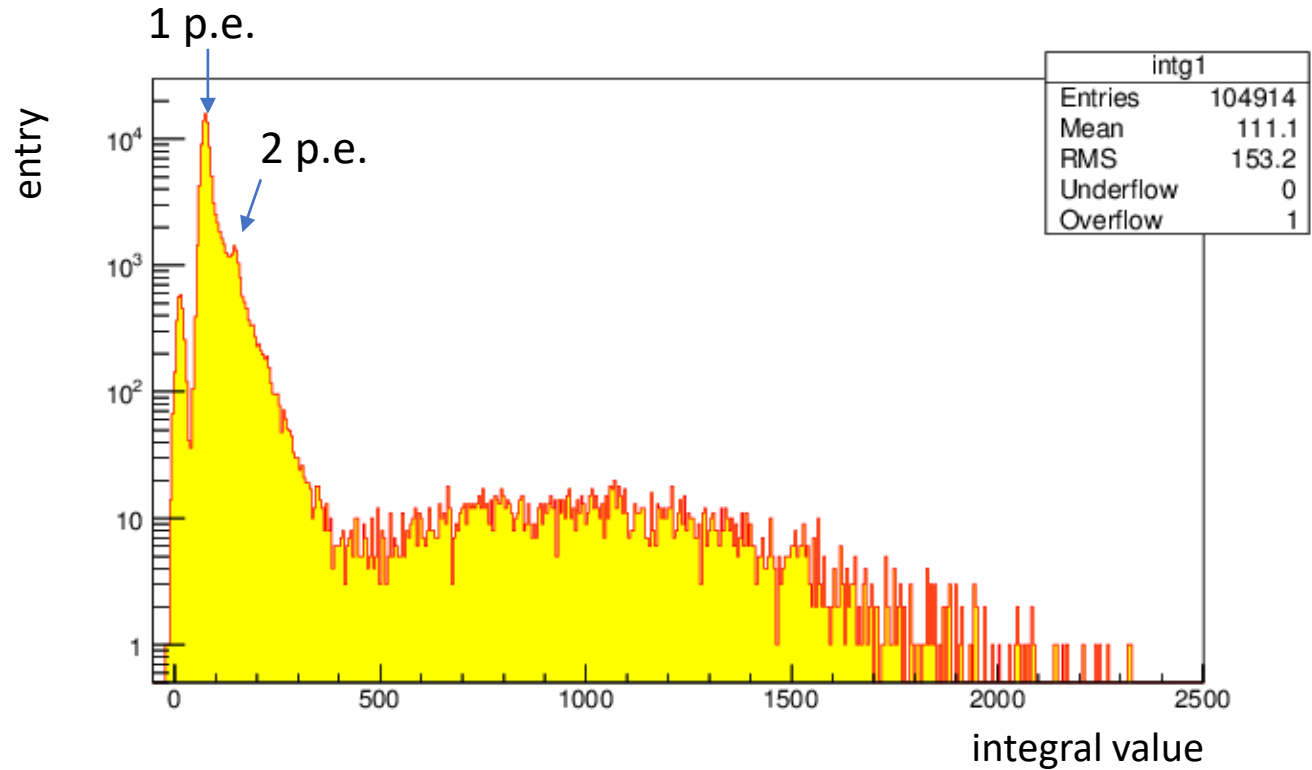
the applied voltage was 0.1 V higher than the calibrated value.

→ Several % of peculiar noises of MPPC might increase.

Derivation of the number of the photons

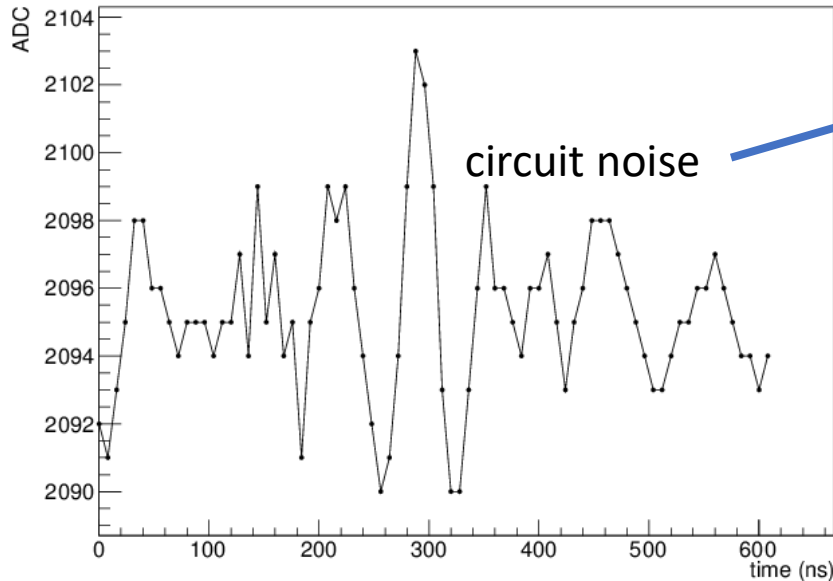
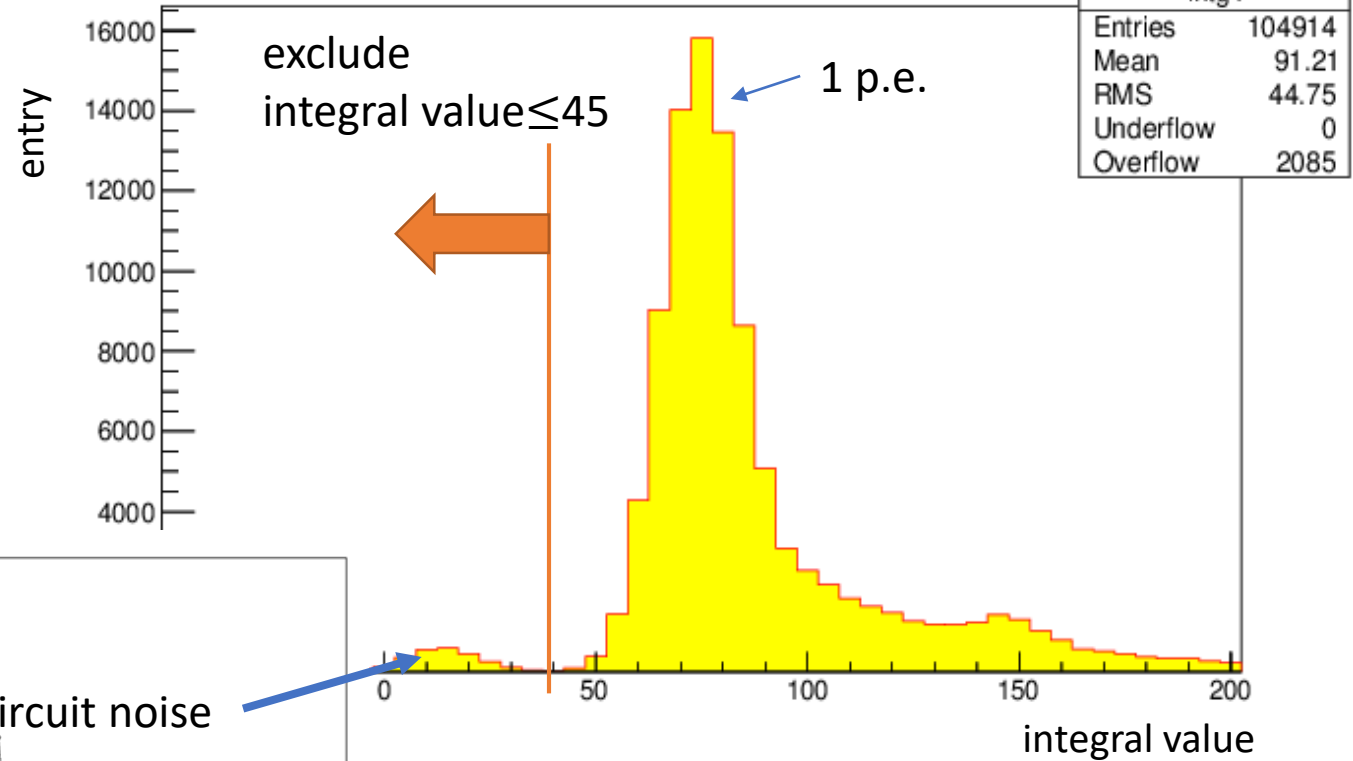
ex. @88 K
irradiated α to NIT

p.e. : photoelectron

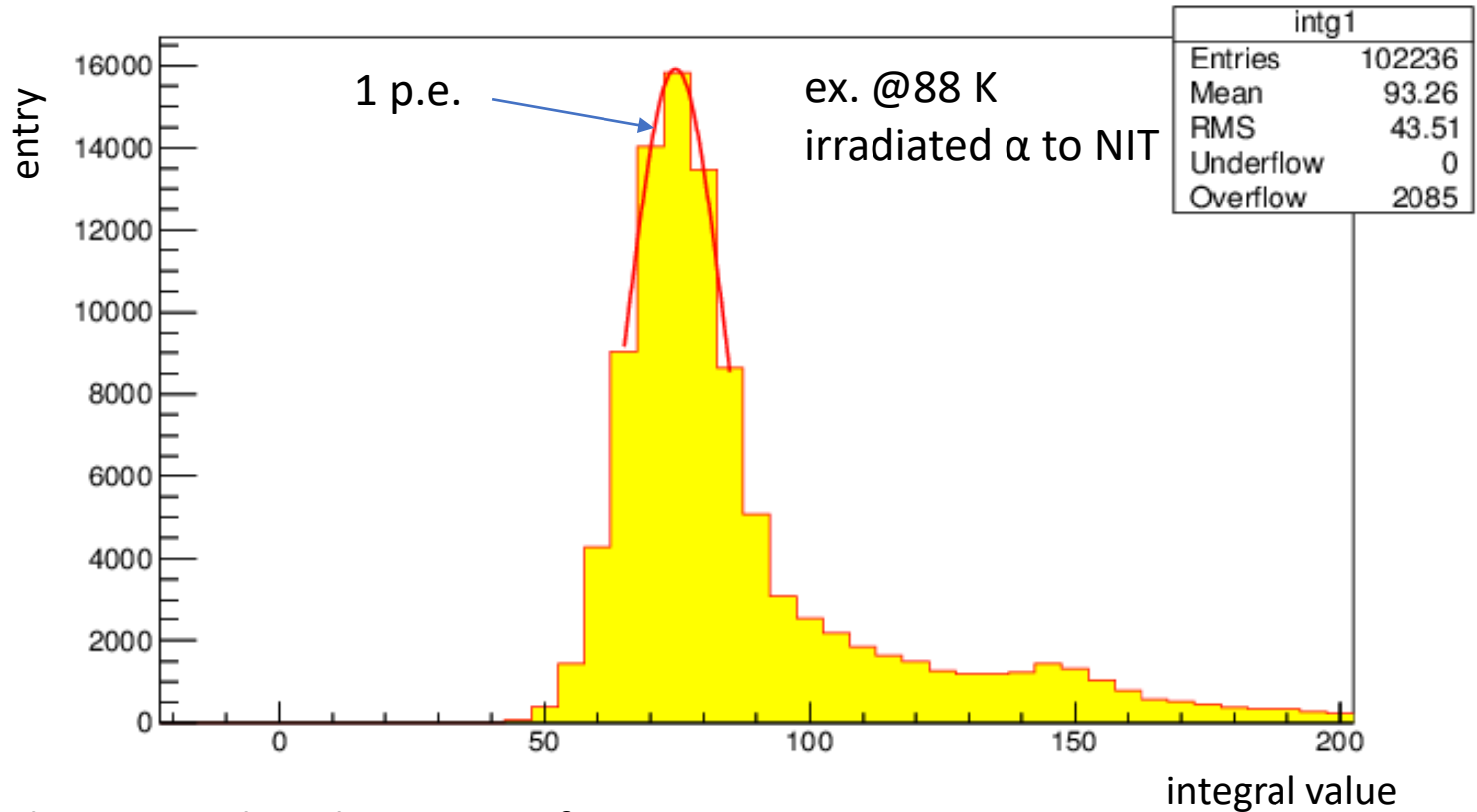


Derivation of the number of the photons

ex. @88 K
irradiated α to NIT



Derivation of the number of the photons

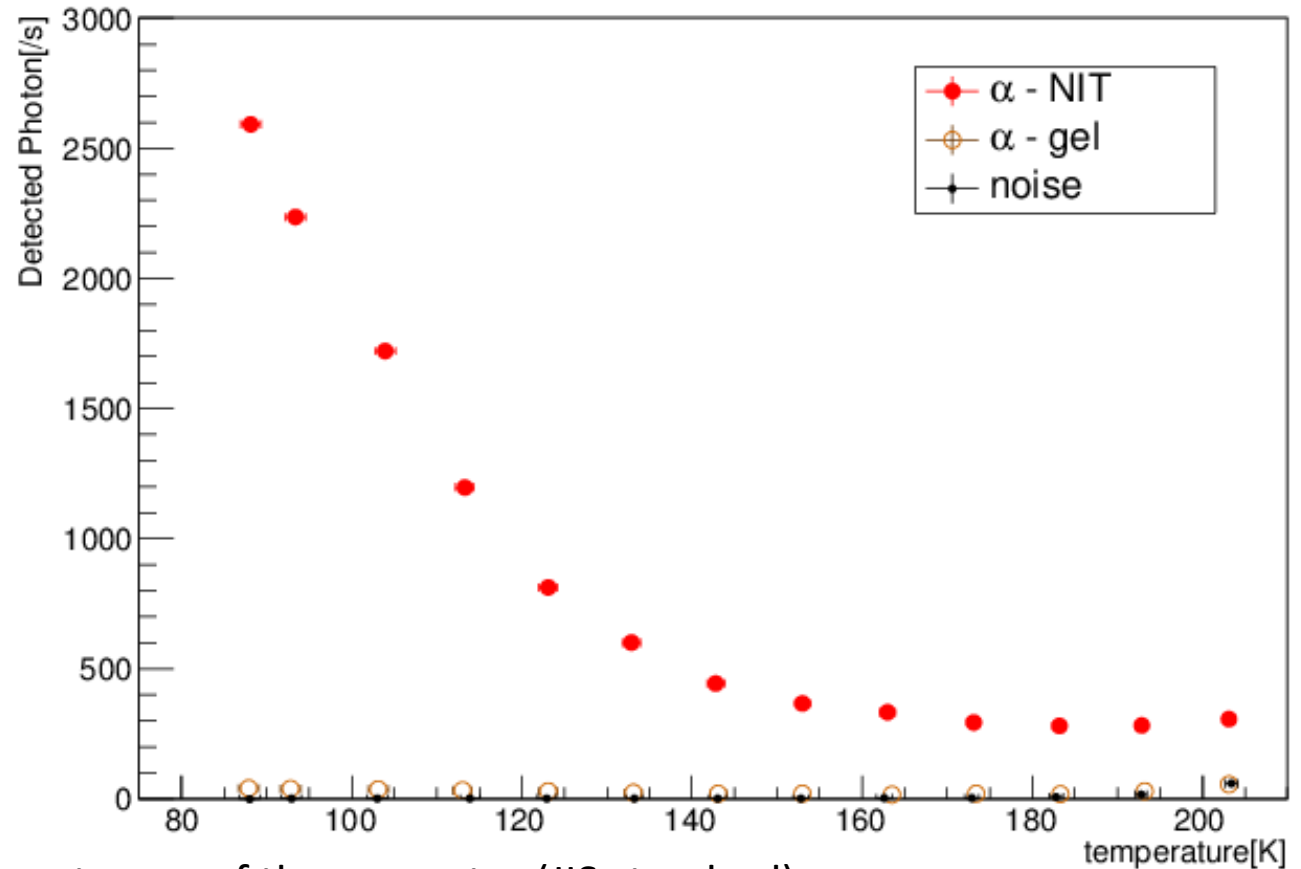


- Obtained 1 p.e. peak with Gaussian fit.
- Regarded the mean value of fitting result as integral value corresponding to one photon. (We call this value “gain”)

- $$\frac{\text{the area of the light quantity distribution}}{\text{"gain" (mean value of fitting result)}} = \text{the number of photons}$$

results

α ray irradiation result

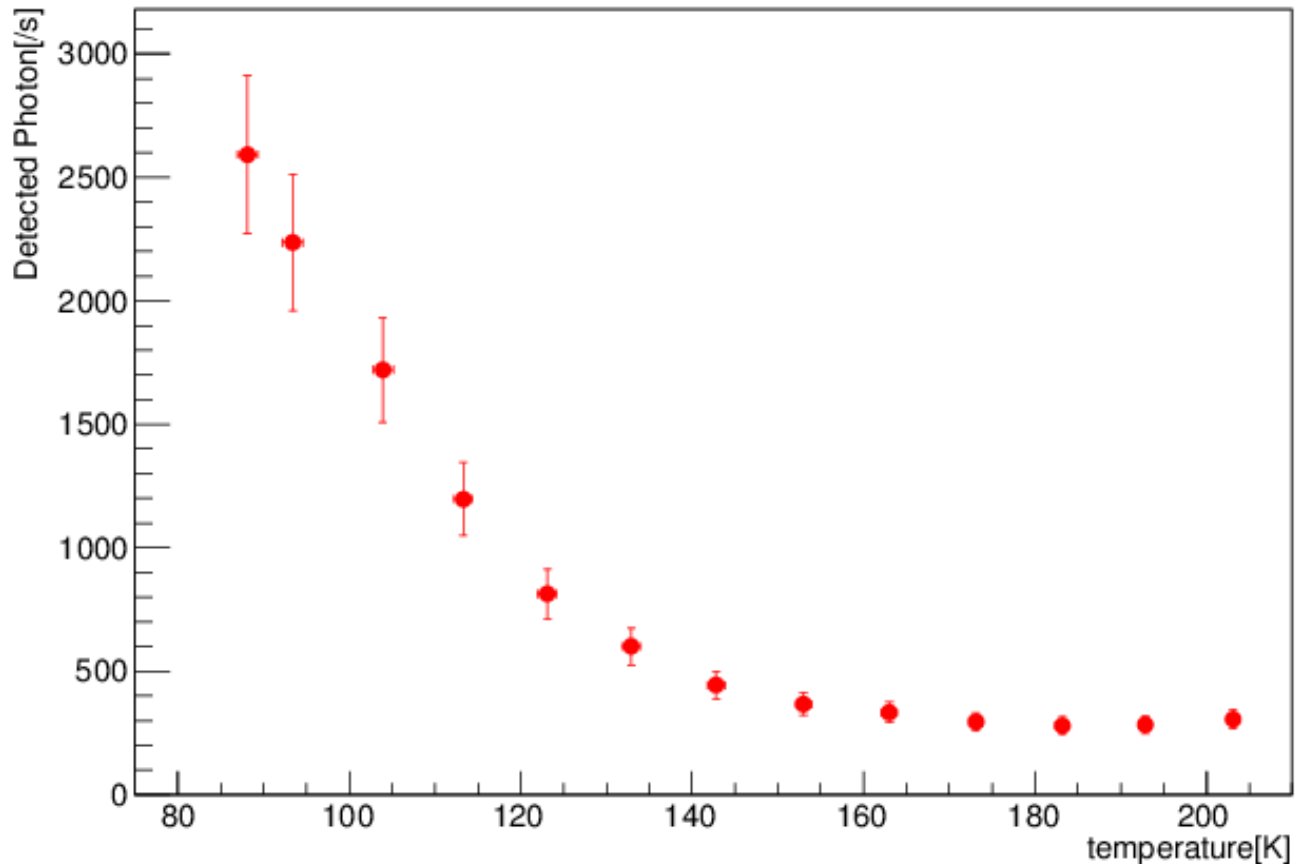


error for temp. : Measurement error of thermometer (JIS standard)

errors for detected photon :

- determination accuracy of 1 p.e. peak $\sim 1\%$
- # of irradiated α ray $\sim 2.2\%$
- peculiar noises of MPPC (cross talk & after pulse ratio) $\sim 10\%$
- repeatability $\sim 6.8\%$

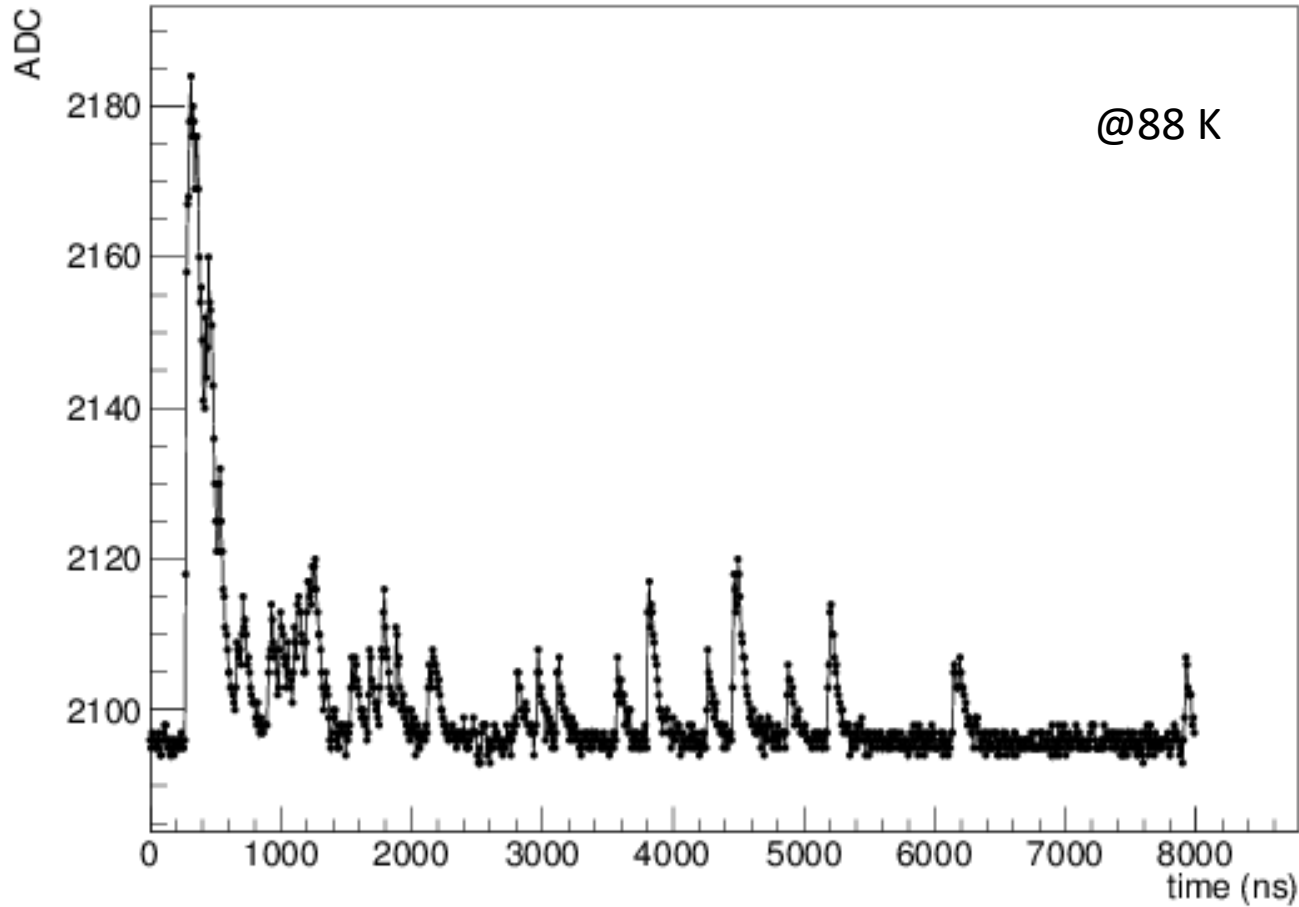
Temperature dependence of luminescence by α ray irradiation



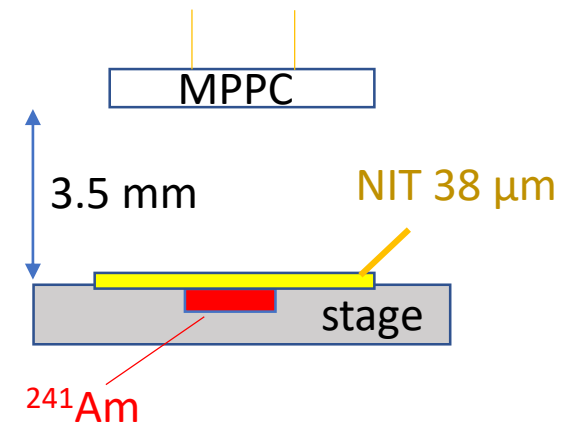
Detected significant excess !

of photon emission was saturated at high temperature (>140 K)

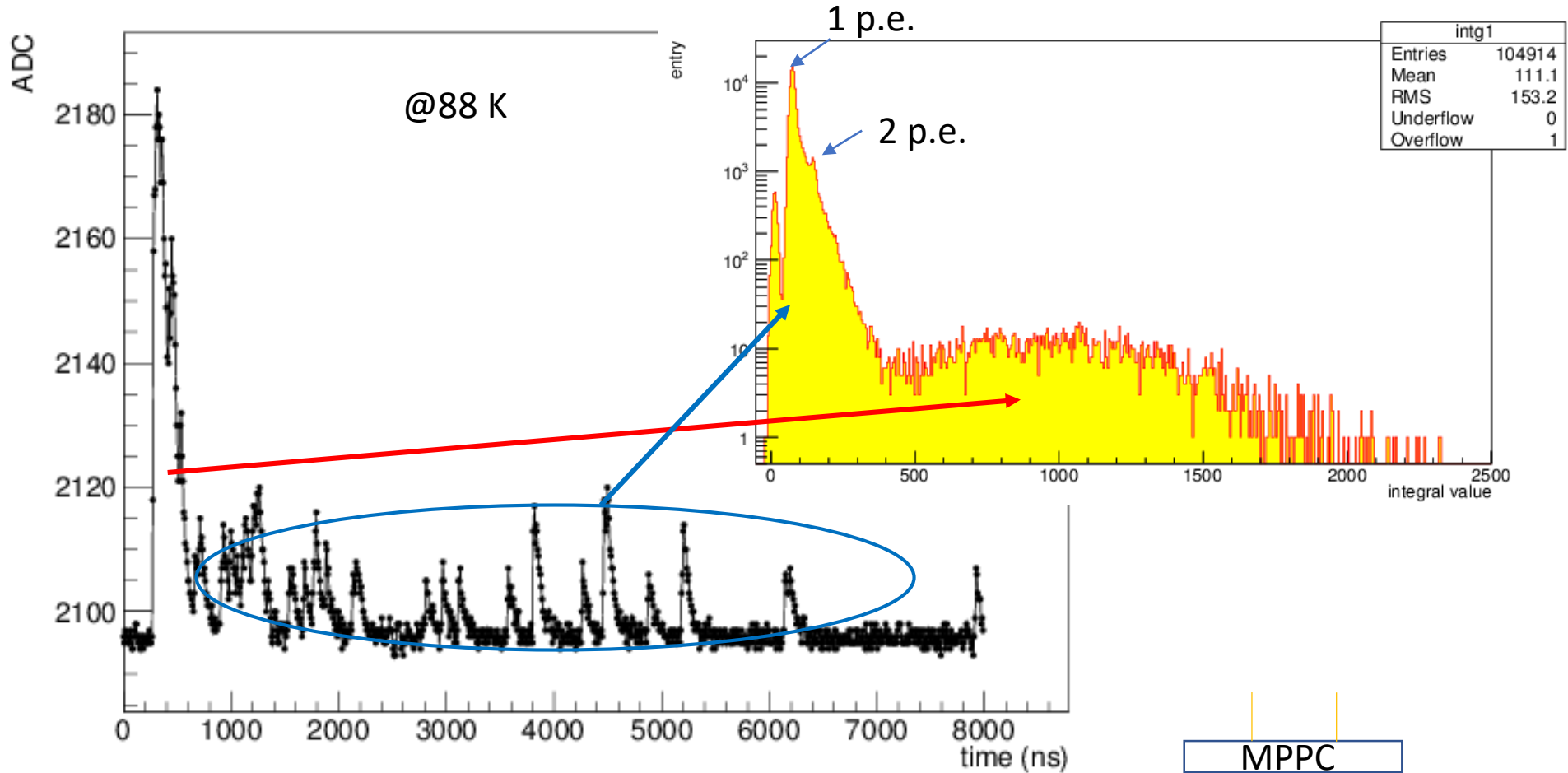
the emission waveform for one α -ray



Trigger threshold : ADC 2143 (triggered signal ~ 33 cnt/s)

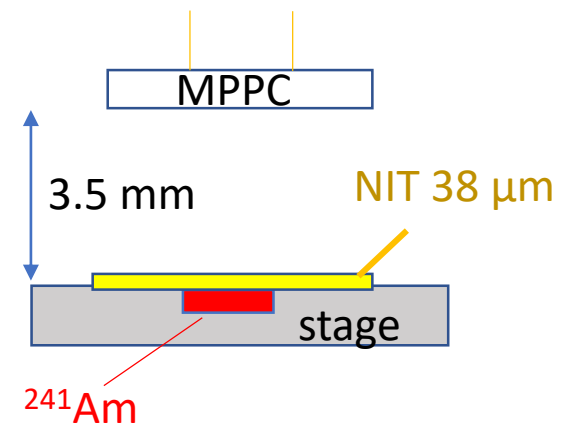


the emission waveform for one α -ray

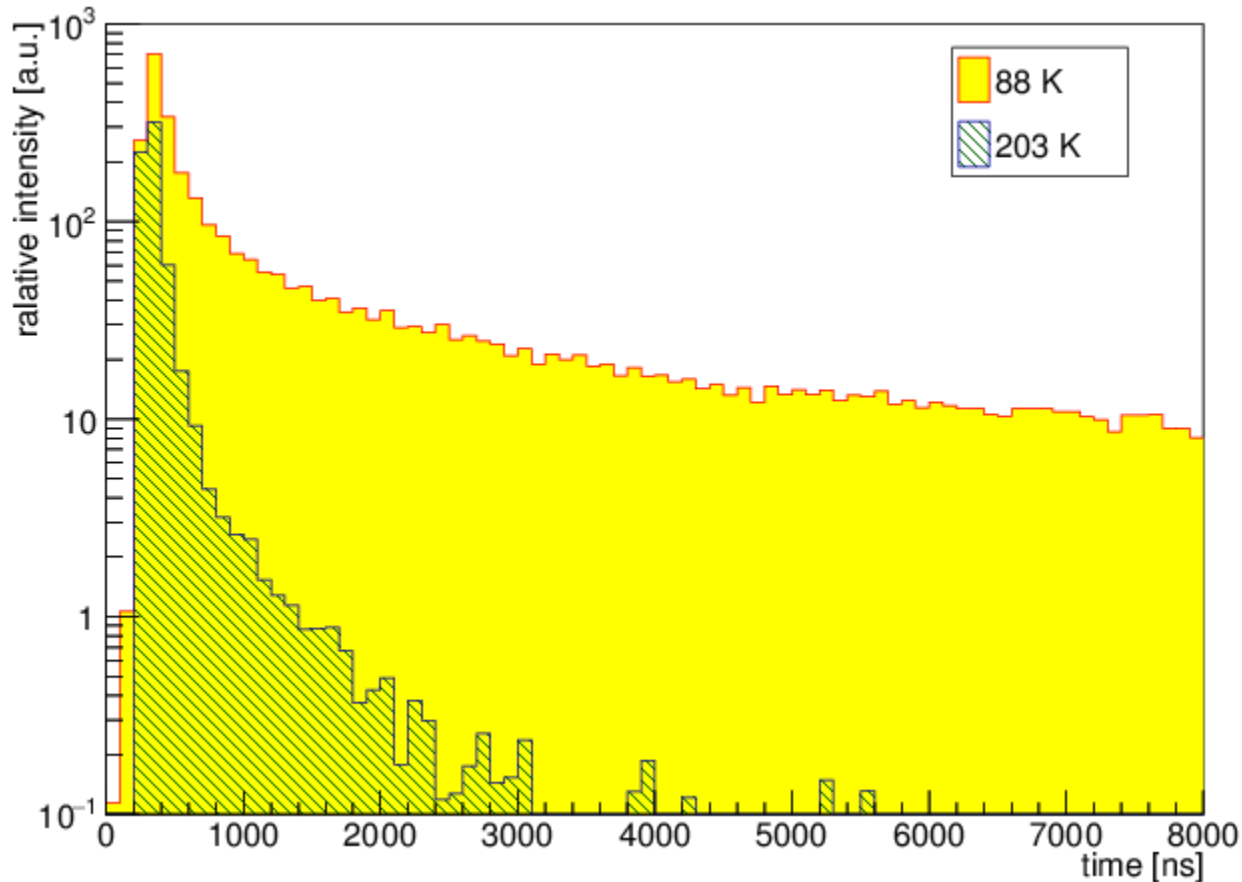


Trigger threshold : ADC 2143 (triggered signal ~ 33 cnt/s)

Performed data acquiring 88 K & 203 K for 30 s
→ compared two waveforms



comparison of emission waveform



@ high temp (203 K) : the slow components (phosphorescence) decrease
fast components (fluorescence) become dominant

→ Fluorescence is caused by the formation of enormous e-h pairs

at the moment when α rays pass.

expect : the luminescent properties vary corresponding to dE/dx (or the particles)

Energy conversion efficiency to luminescence

(Energy conversion efficiency to luminescence) = 5.8* (# of detected photons)

$$\frac{\text{energy deposit in the AgBr}}{\text{transmittance}} \times \text{Geometric detection efficiency} \times \text{photon detective efficiency of MPPC}$$

Geant4 simulation
6.6 MeV (ave.)

$T [\%] = 82.3 * \exp(-0.0165 * x)$
T : transmittance、 x : thickness

Calculation from setup
~5.8%

reference value 32%
(298 K、 $V_{over} = 4$)

- Dead time of Cosmo-Z (ADC board) ~13 % (corrected)
- Loss due to transmittance of glass ~8 % (corrected)

errors considered:

- Transmittance of NIT ~5 %
- Determination accuracy of 1 p.e. peak ~1%
- # of irradiated α ray ~ 2.2%
- Peculiar noises of MPPC (cross talk & after pulse ratio) *~10 %
- Repeatability ~6.8 %

Assumed wavelength 577 nm
(phosphorescence)

*T. Igarashi, master's thesis, Waseda Univ.

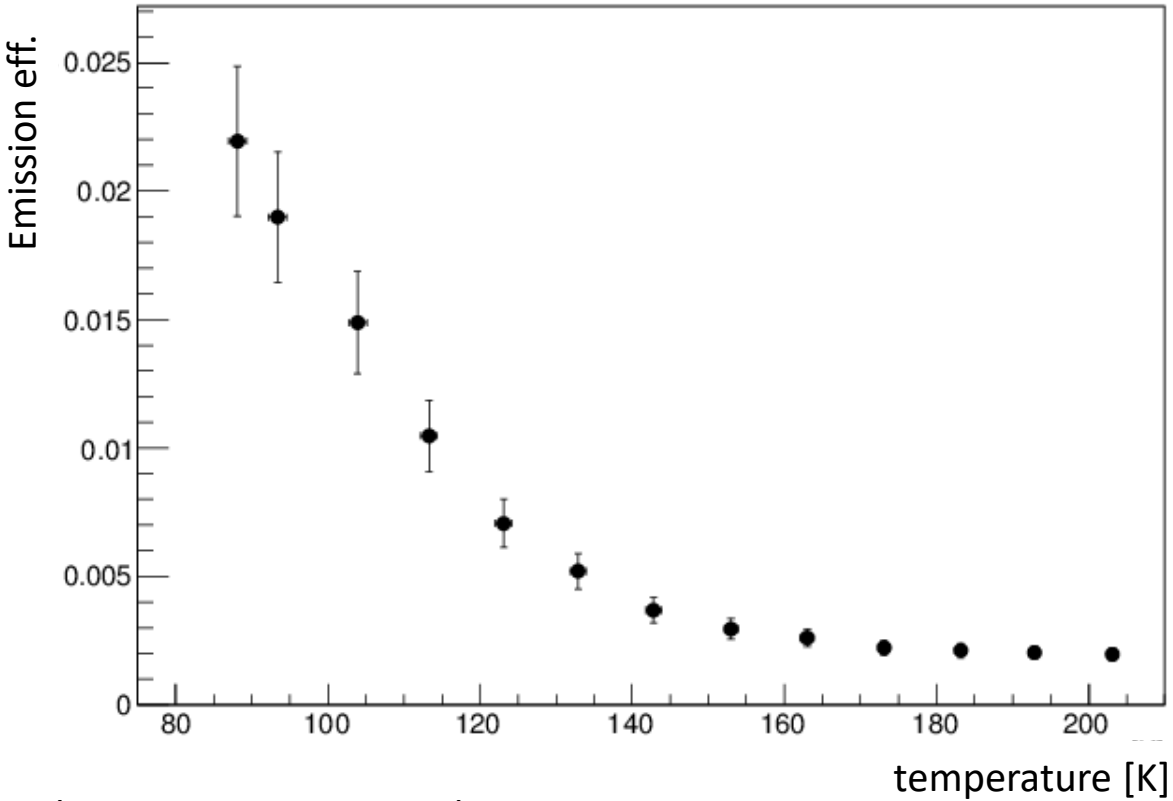
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$$\frac{\text{(energy deposit in the AgBr)}}{\text{(transmittance)}} \cdot \frac{\text{(Geometric detection efficiency)}}{\text{(photon detective efficiency of MPPC)}}$$

- Geant4 simulation
6.6 MeV (ave.)
- $T [\%] = 82.3 \cdot \exp(-0.0165 \cdot x)$
T : transmittance、 x : thickness
- Calculation from setup
~5.8%
- reference value 32%
(298 K、 $V_{over} = 4$)

Assumed wavelength 577 nm
(phosphorescence)



(Luminescence by bound excitons : *496 nm → 1.4 times)

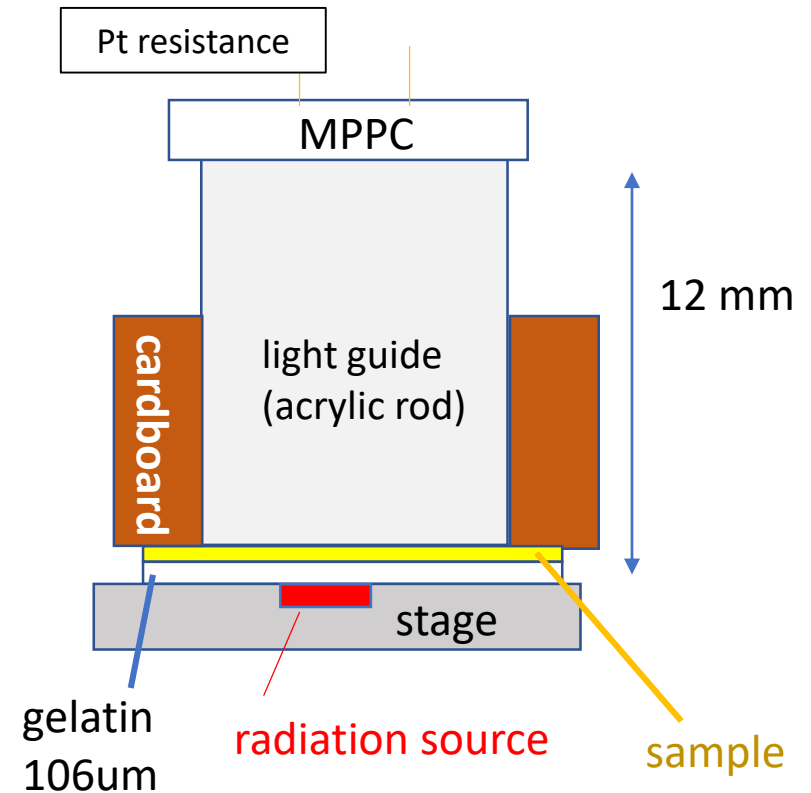
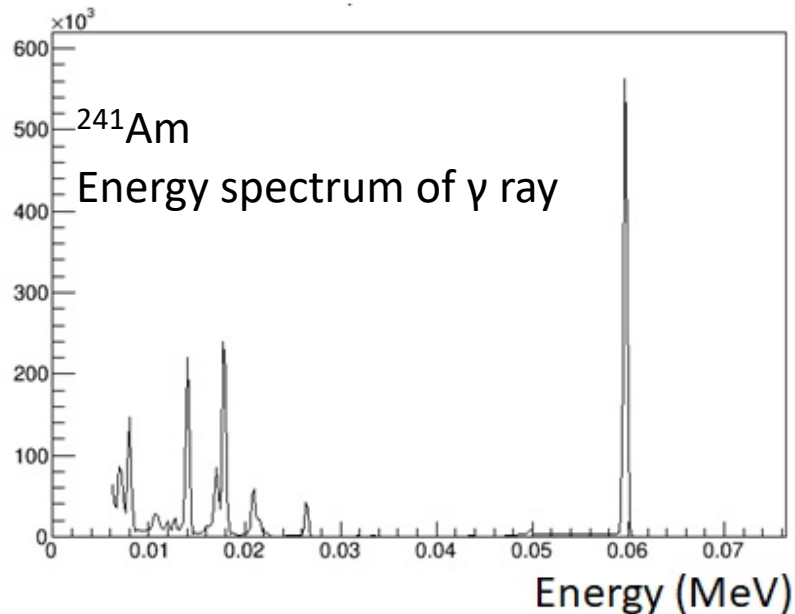
*H. Kanzaki, J. Soc. Photogr. Sci. , 49-5 (1986)

irradiation of γ ray

irradiation of γ ray

energy of γ ray is low

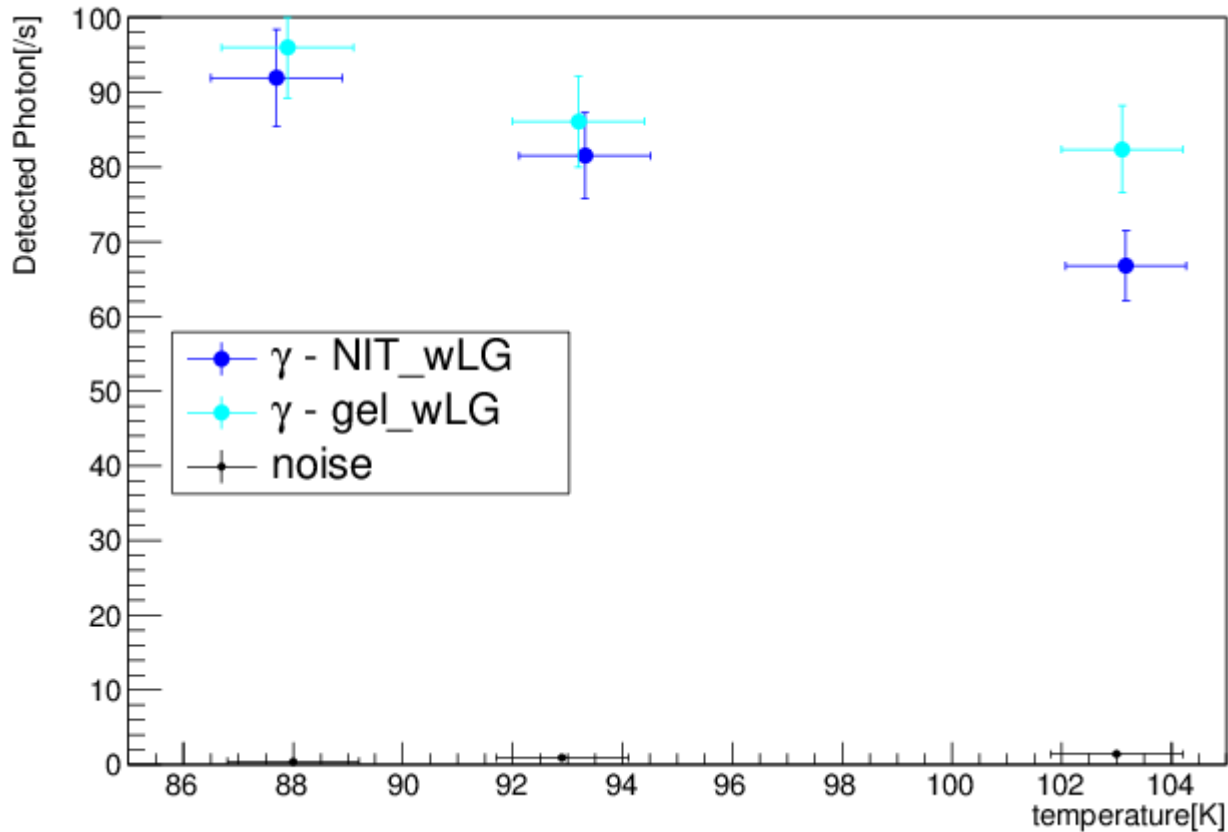
- to reduce γ entering MPPC directly
- not reduce light intensity



used samples

NIT 37 μm *7mm*3 mm (pellicle : w/o base)
gelatin 40 μm *3 mm*7 mm

result



We observed something luminescence.

There is no difference between samples (NIT and gelatin).

It is necessary to verify what the detected signal is.

summary

- evaluated emulsion from a new viewpoint of luminescence independent of silver particles (tracks) observation
 - Understanding of physical properties of crystals
 - Application to elementary particle experiment

(1) Observation of luminescence with human eyes

- Confirmed the phosphorescence, wavelength peak was about 577 nm
- Confirmed the luminescence of emulsion by charged particle

(2) Quantitative evaluation for luminescence by charged particle

α ray :

- Observed luminescence from 88 K to 203 K.
- Confirmed the components of fluorescence.
- Ene. conversion efficiency to luminescence @ 88 K was 2.2 %.

→ equivalent to plastic scintillator (Assumed emission wavelength of 577 nm)

γ (β) ray :

- Quantitative evaluation of luminescence has not been achieved.
(luminescence by β ray was confirmed by another test)

→ update the measurement system to perform quantitative evaluation

prospects

Understanding of physical properties of crystals

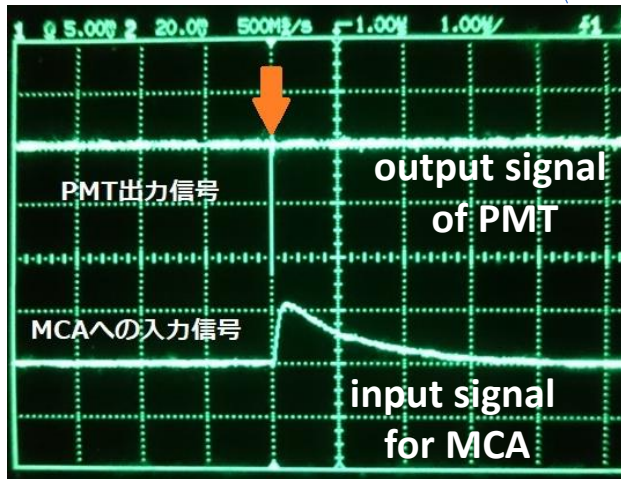
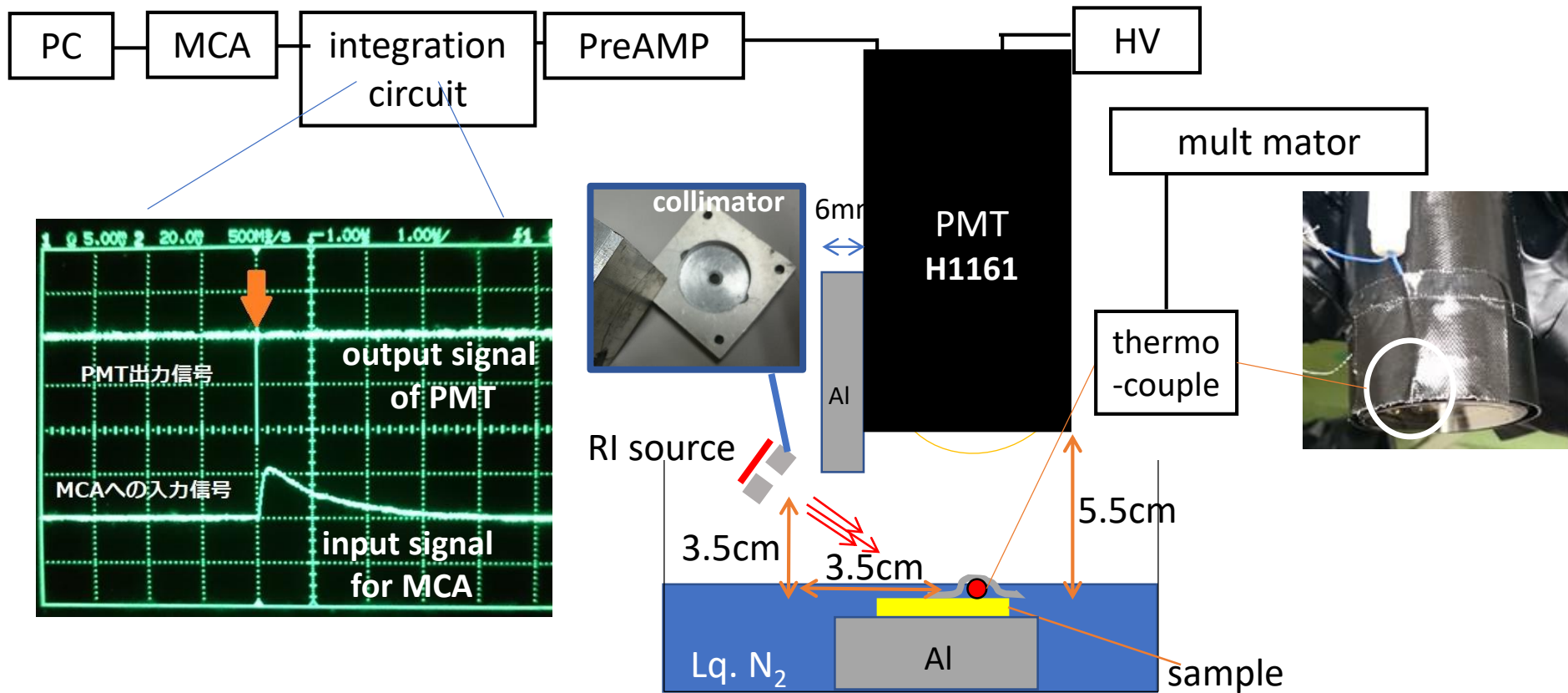
- Measurement of luminescent spectrum
 - Identification of emission wavelength
 - Phenomenology at the moment when charged particles pass through the crystal
- Observe the change in the luminescent properties when changing the crystal size and doping

Application to elementary particle experiment

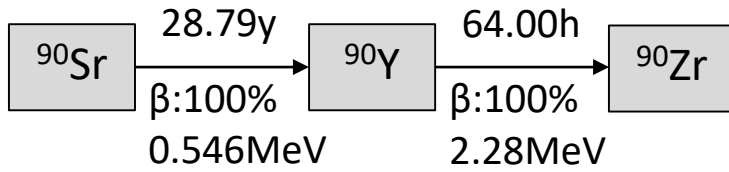
- Observe the luminescence caused by γ (β) ray and nuclear recoil
 - Comparing difference in luminescence of each particles :
 - Relationship between dE / dx and emission intensity
 - Difference of luminescent properties (time constant, wavelength)
 - the key is nuclear stopping power
- Narrow down the event location by using luminescence
(Combined analysis of tracks observation and light emission)

back up

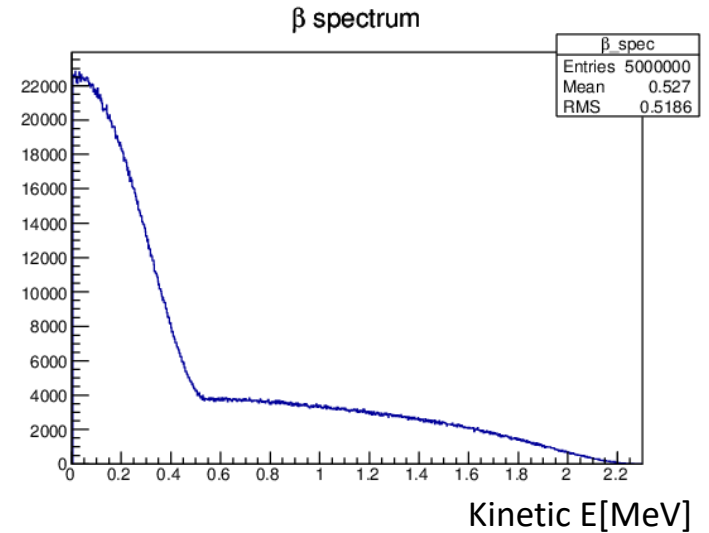
measurement system



RI source: Sr90(β source)



Activity: ~594kBq
 (D.C.1990 → D.C.2016)
 rate of β (@NIT) : 1160[/s]



used samples

NIT 150 μm * 10.9 cm^2 (薄膜)

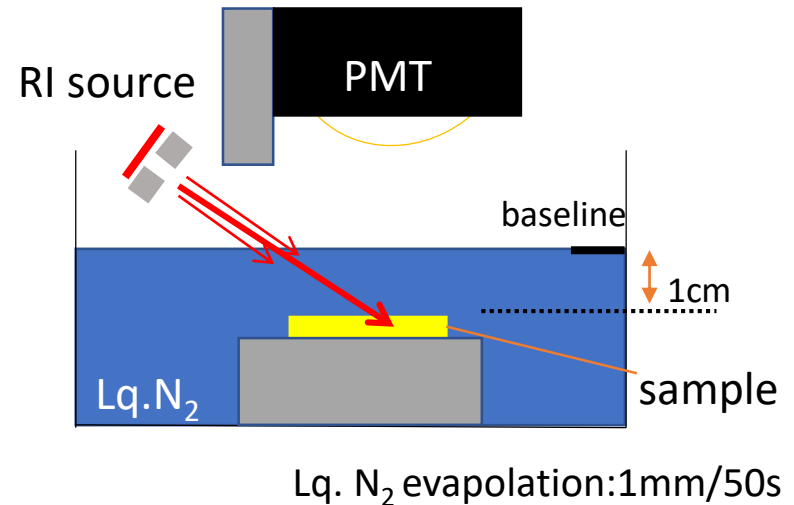
Gel.: gelatin 80 μm * 10.8 cm^2 (60% of film)

測定手順

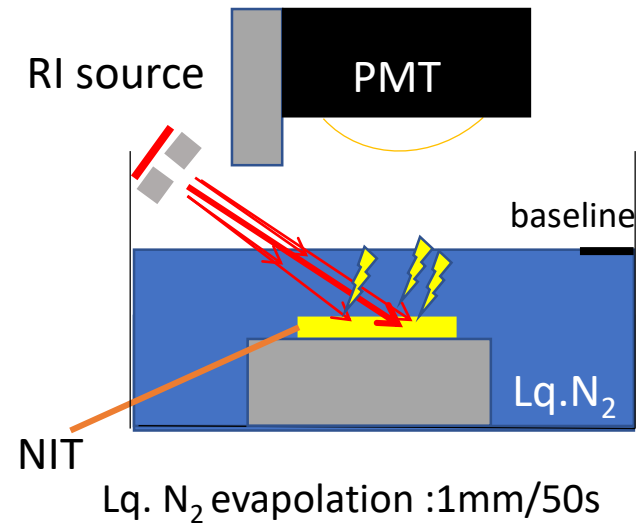
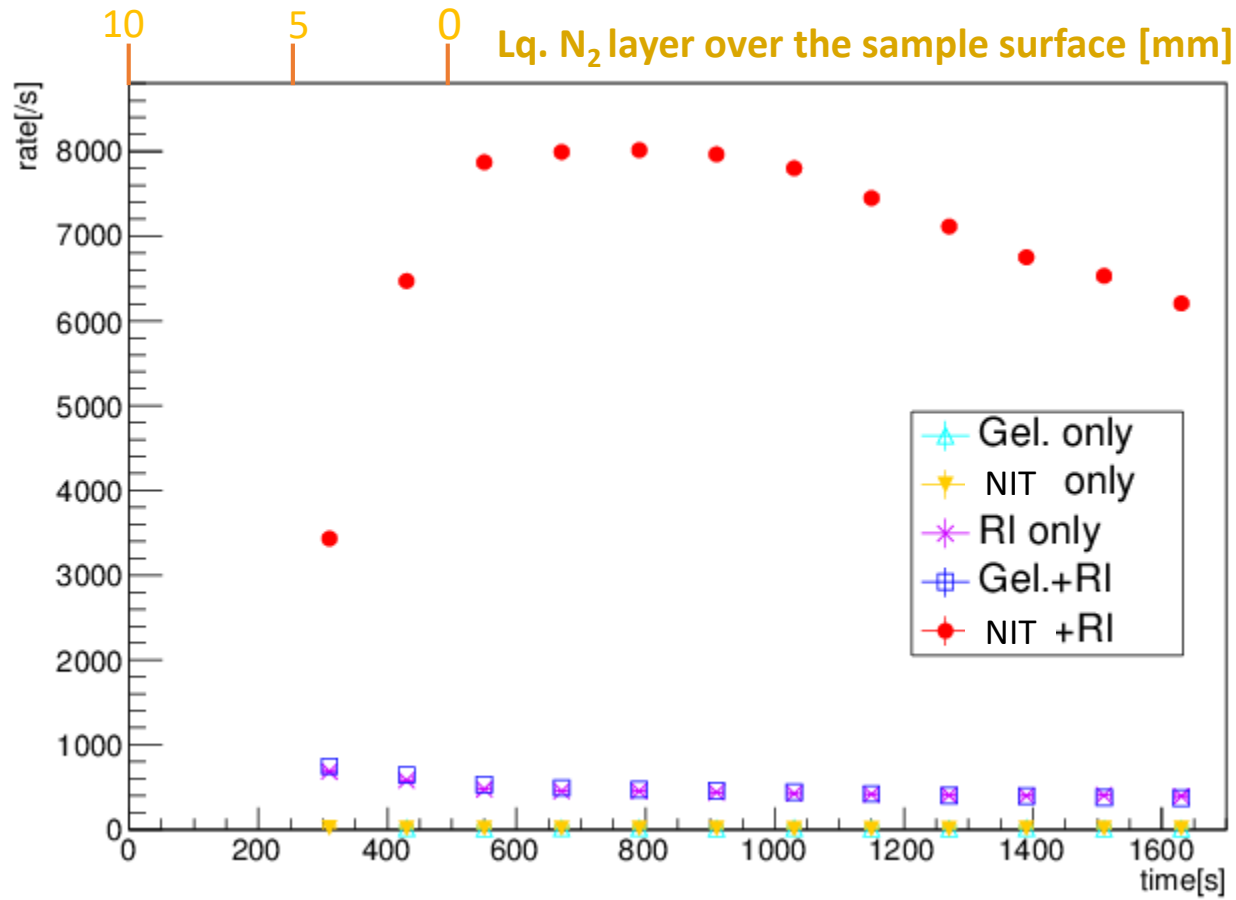
- LN2を基準線まで注ぐ
- 暗幕をかけ、PMTに電圧をかける
- 2分ごとに20秒間MCAでデータ取得
(MCSモード：単位時間当たりの信号数カウント)

- set only the sample (Film/Gel.)
- set only the radiation source (RI)
- set the sample and radiation

measurement was performed in these 5 situation

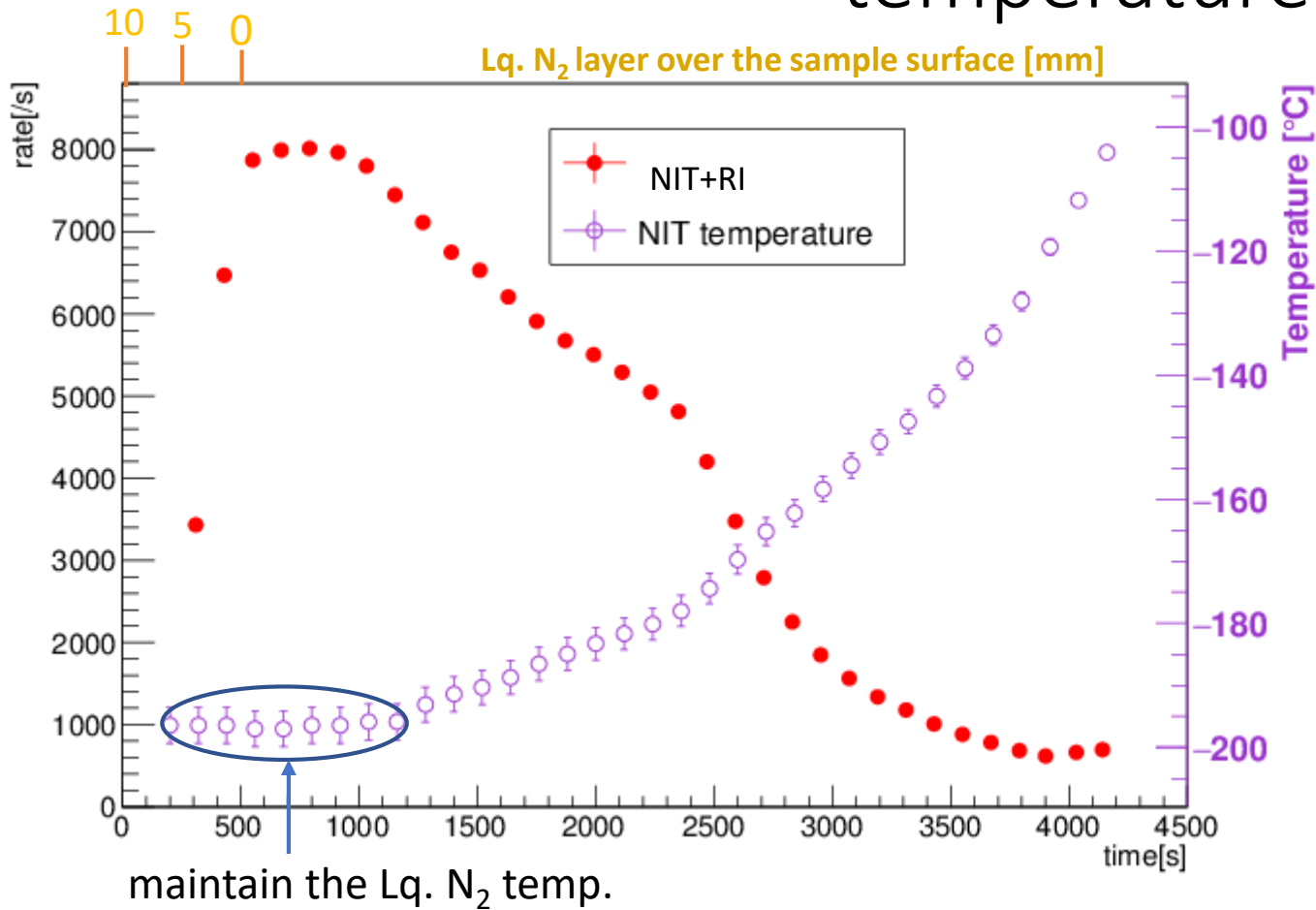


result



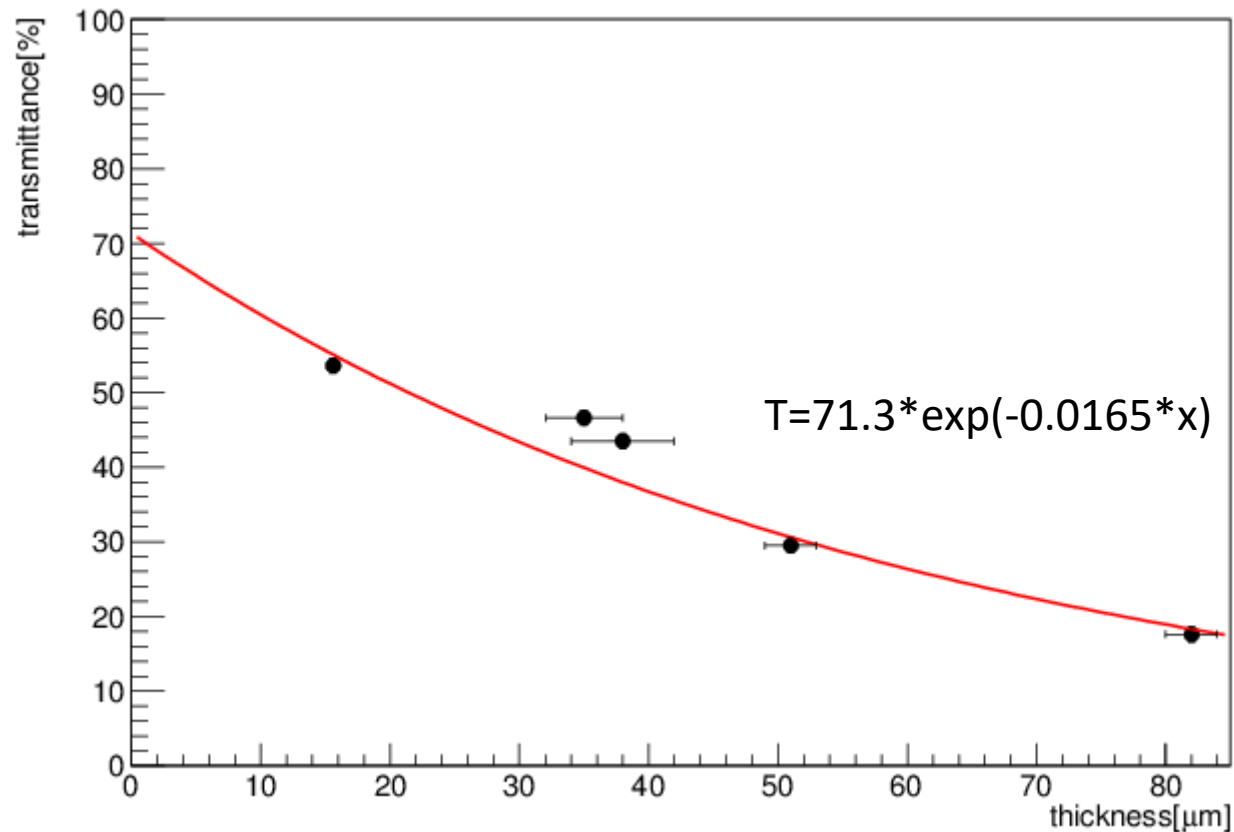
Correspondence between NIT

temperature and rate



Temperature control did not achieve.

thickness of NIT VS transmittance

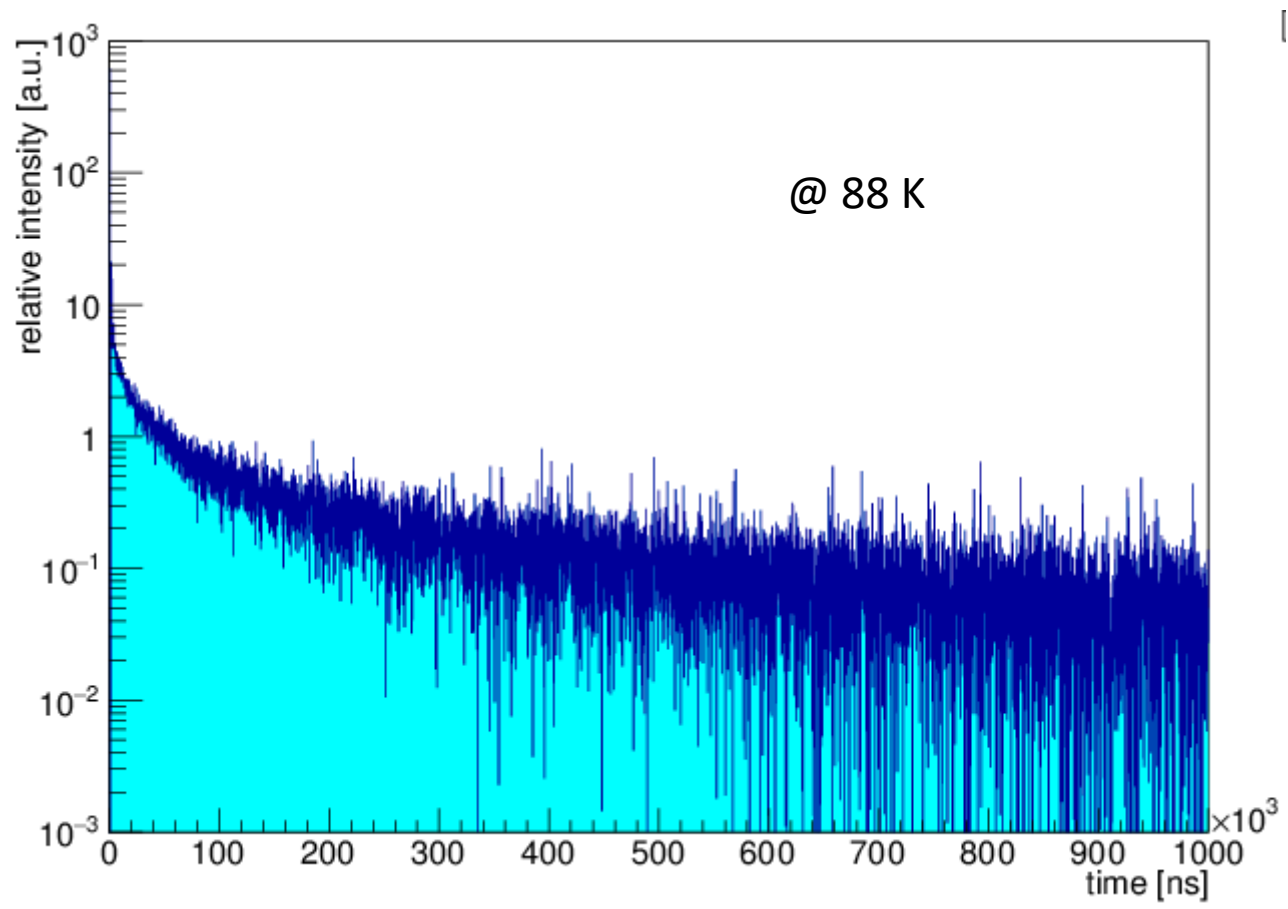


透過率と厚み (経路長) の関係 : $T = A * \exp(-ax)$

A : 界面での反射による損失、T : 透過率、a : 吸収計数、x : 厚み (経路長)

実際の測定では光はNIT中で発生し、表面での反射の影響は一度。一度の反射での損失は反射率をRとすると $(1-R)^2 = 0.713$ を解けばよく、 $R = 0.155$ が得られる。

$T = 82.3 * \exp(-0.0165 * x)$

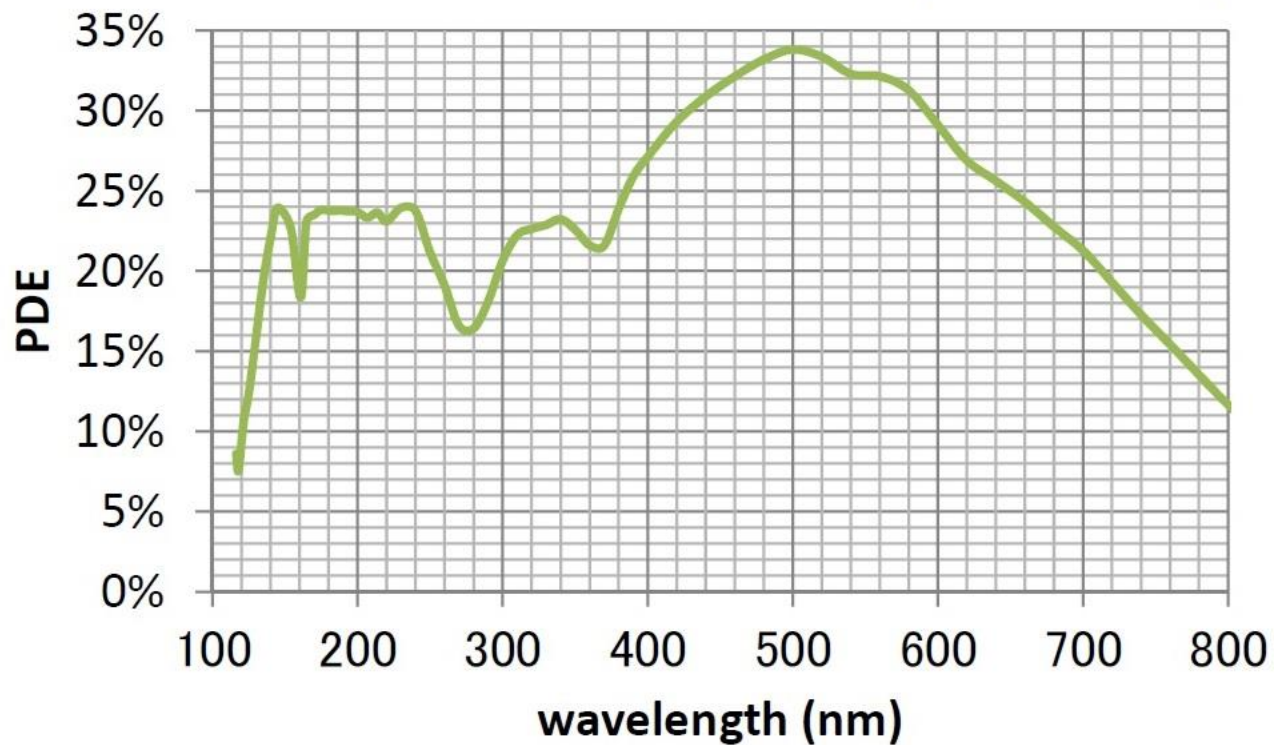


Phosphorescence lasts tens of μs .

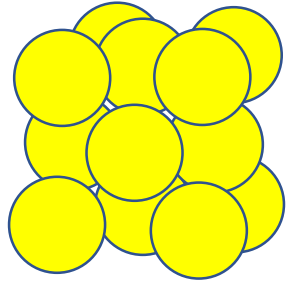
PDE of MPPC

REFERENCE DATA

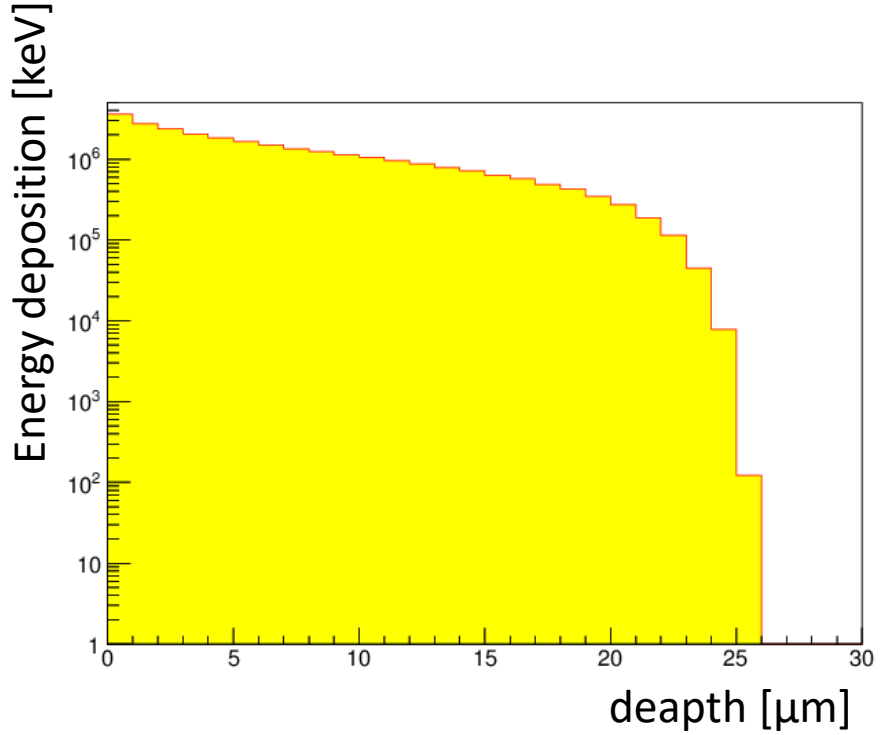
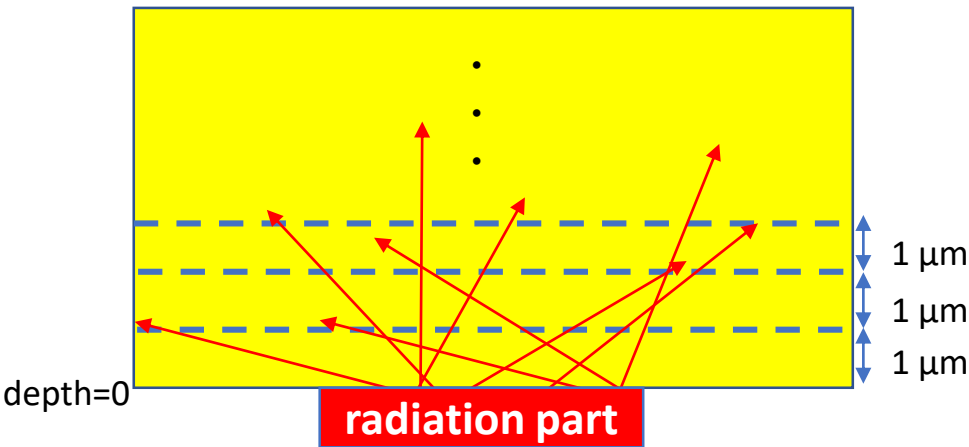
S13370-3050CN PDE (V_{over} = 4V)



Geant4 simulation

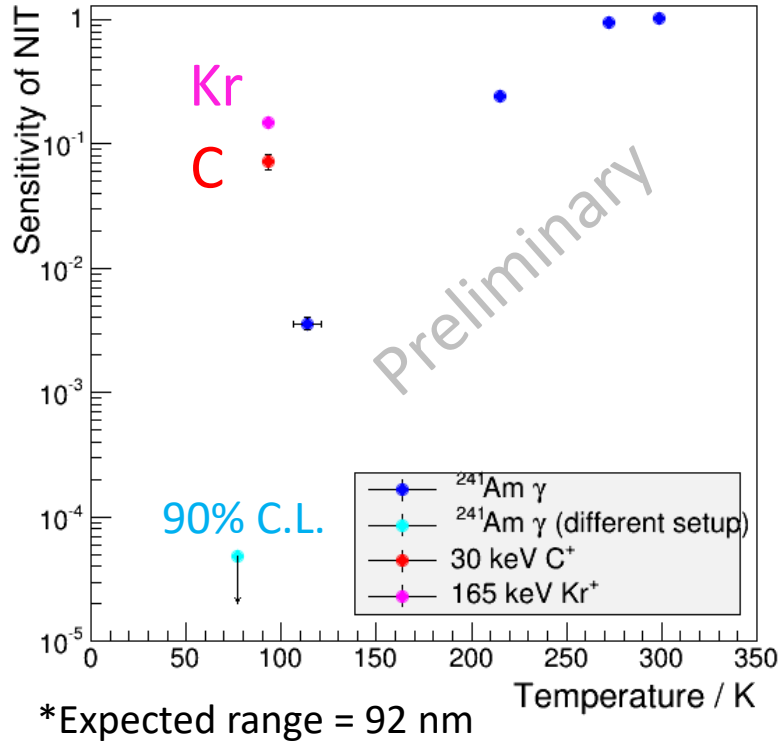


- Construct the same geometry as measurement
- The AgBr crystals are arranged in face-centered cubic lattice in NIT.
- Set composition and density with reference to Asada san's paper*
- Irradiate 10000 alpha rays (5.48 MeV), calculate energy deposition in the crystal every 1 μm layer.
- exclude the event which energy deposition in the crystal is lower than 5.8 eV



NITの低温でのふるまい(銀核生成)

日本物理学会
2016春季大会で報告



sensitivity \equiv (目で測定された現像銀数) / (期待される現像銀数)

低温において：

電子はうつらない

CやKrのイオンはうつる

・核的阻止能(NSP)の寄与

→結晶の温度上昇

⇒**銀核生成率の回復**

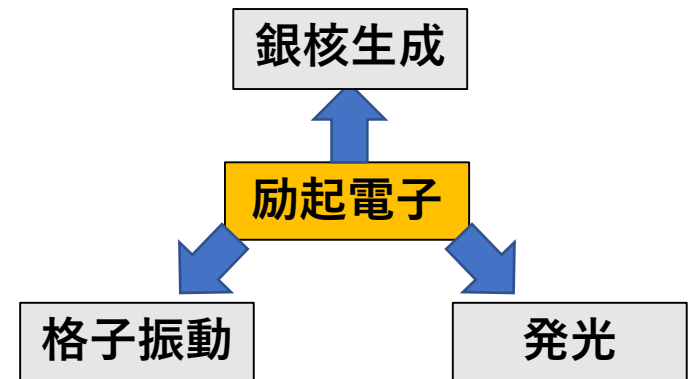
M. Kimura, et al., Nuclear Instruments & Methods in Physics Research A (2016)

上記の結果は新しい知見

発光からのアプローチ

✓ 低温での現象論の理解

✓ 発光にも荷電粒子の違い



MPPCの温度毎の V_{bd} 較正

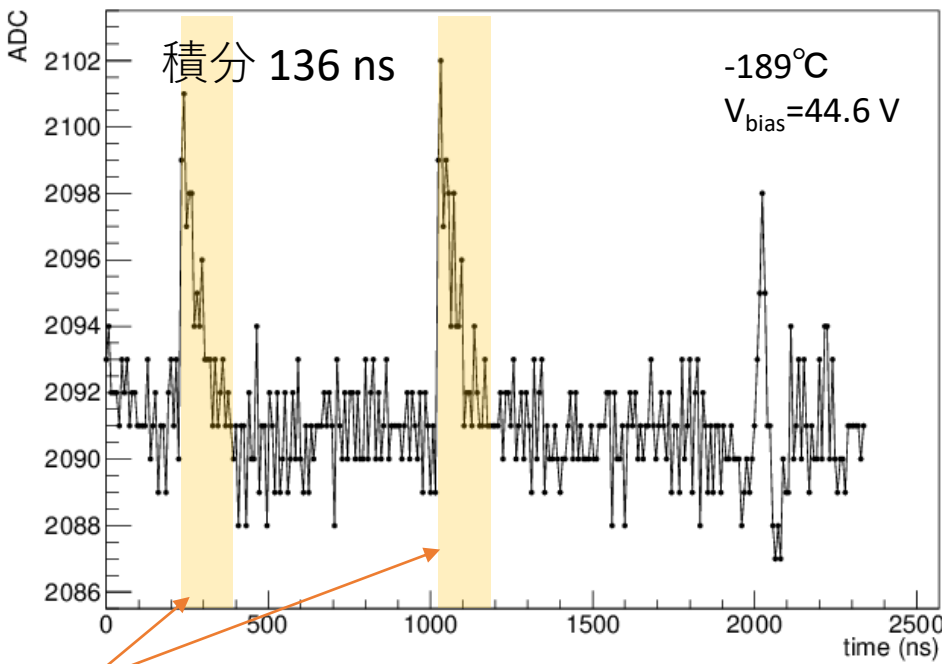
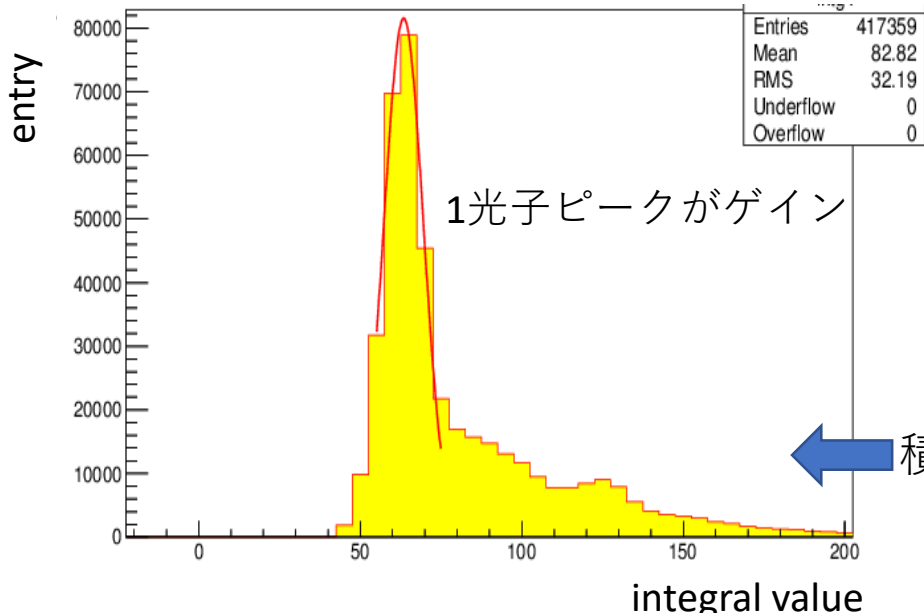
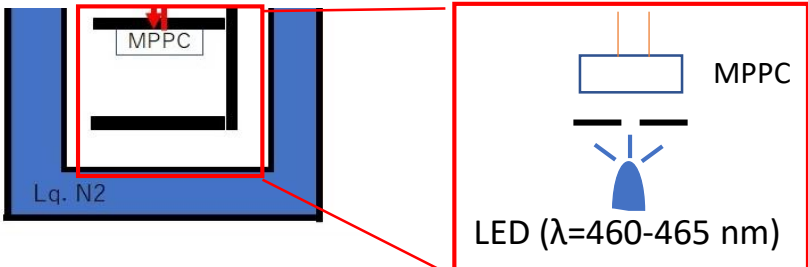
降伏電圧 V_{bd} は温度によって変わる
MPPCのゲインは

$$M = \frac{C(V_{bias} - V_{bd})}{e} \quad (= \frac{CV_{over}}{e})$$

温度を安定させ、 V_{bias} を変えた測定を行うとMと V_{bias} の関係から V_{bd} が求まる。

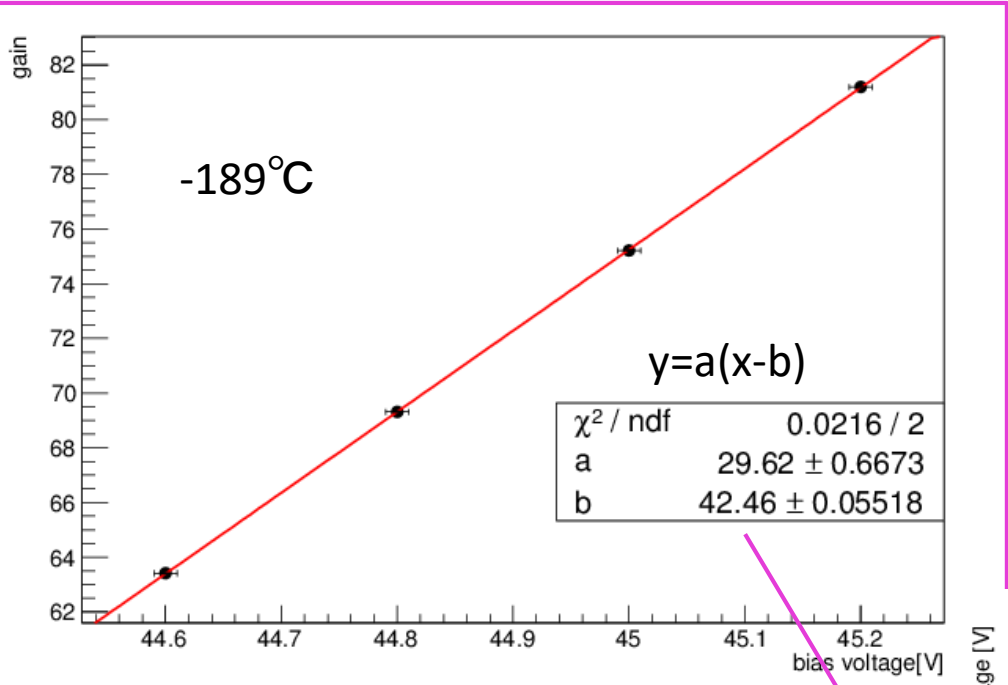
1ピクセルの出力電荷Q
 $Q = C * (V_{bias} - V_{bd})$

C: 1pix.の静電容量、e: 素電荷



積分範囲外の(time<1888 ns)でペデスタルを補正

温度毎のV_{bd}校正



$$M = \frac{A * C(V_{bias} - V_{bd})}{e}$$

縦軸の誤差：

- 4点測定する間の温度上昇
- 1光子ピークの決定精度

横軸の誤差：

- 設定できる最小単位

横軸の誤差：
 • 温度計の測定誤差

